

Manipulating Polariton Condensates on a Chip

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ISSO 12
St. Petersburg
14.7.12

Acknowledgements

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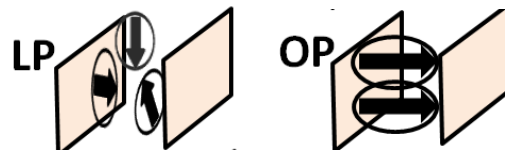
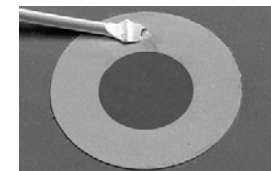
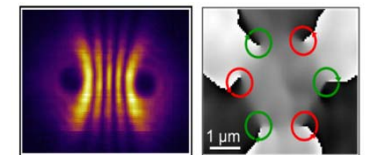
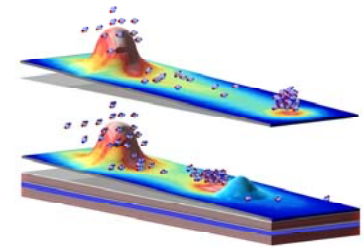
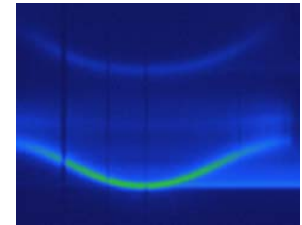
N. Berloff



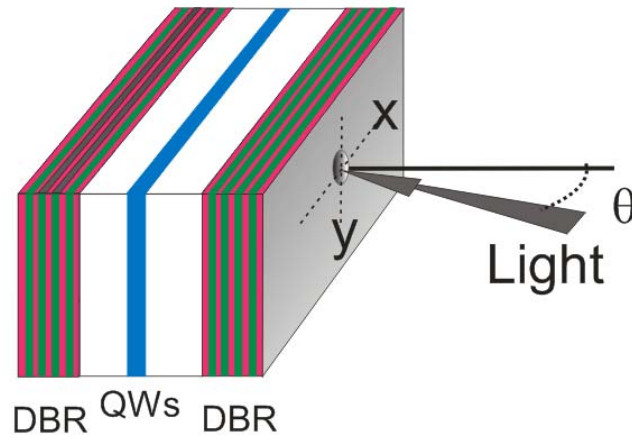
T. Liew
Nanyang Tech. University
Singapore

Outline

- Polariton lasing in high finesse microcavities
 - threshold temperature dependence (strong vs weak)
- Electrical and optical manipulation of polariton condensates on a chip
 - polariton condensate transistor
 - interactions between independent condensates
 - electrical control of polariton condensate
- Dipolaritons: dipole oriented polaritons
 - control of quantum tunneling with light



Strong Coupling Regime in Semiconductor Microcavity

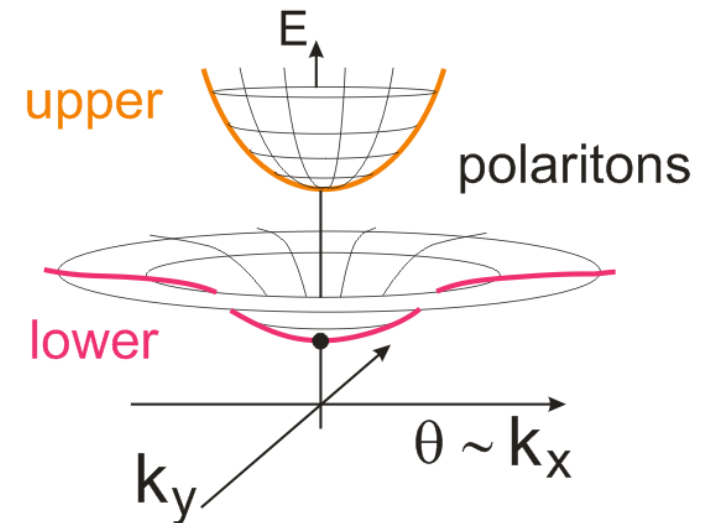
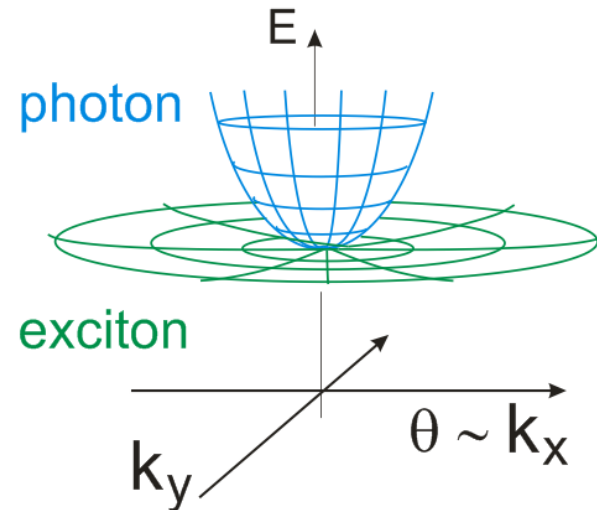


- Strongly modified dispersion relations
new properties
- small polariton mass $m_{\text{pol}} \approx 10^{-4}m_e$

Strong Coupling Regime

$$E_{\text{photon}} = \frac{\hbar c}{n_c} \sqrt{\left(\frac{2\pi}{L_c}\right)^2 + k_{\parallel}^2}$$

$$E_{\text{ex}}(k_{\parallel}) = E(0) + \frac{\hbar^2 k_{\parallel}^2}{2M_{\text{exciton}}}$$



C. Weisbuch et al., Phys. Rev. Lett. 69, 3314 (1992)

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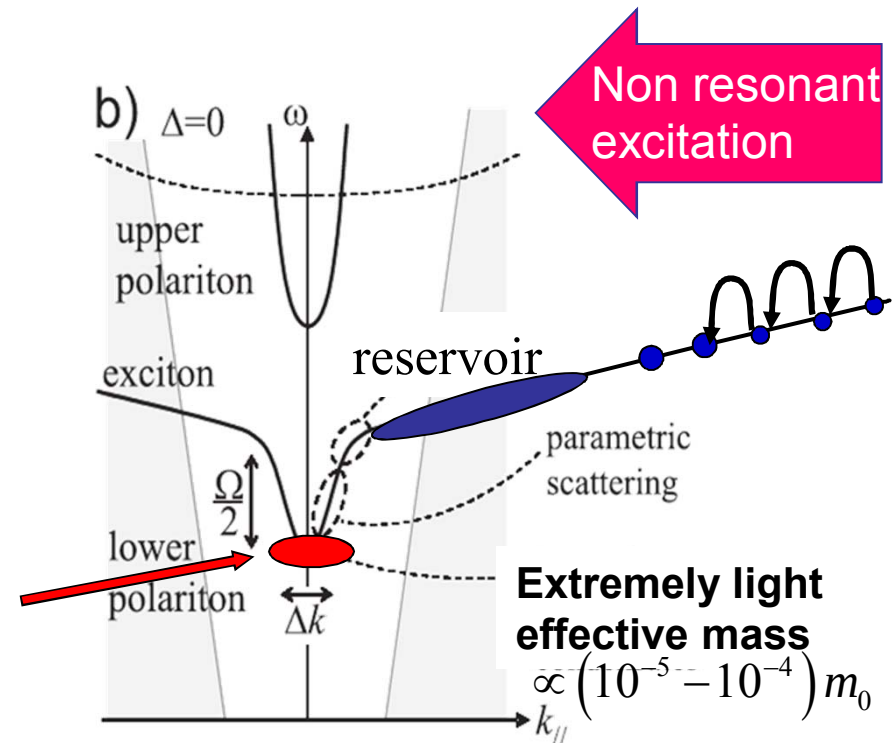


Bose-Condensation and Concept of Polariton Lasing

Imamoglu et al., PRA 53, 4250 (1996)

Bosonic character of cavity polaritons could be used to create an exciton-polariton condensate that would emit coherent laser-like light.

Polariton condensate

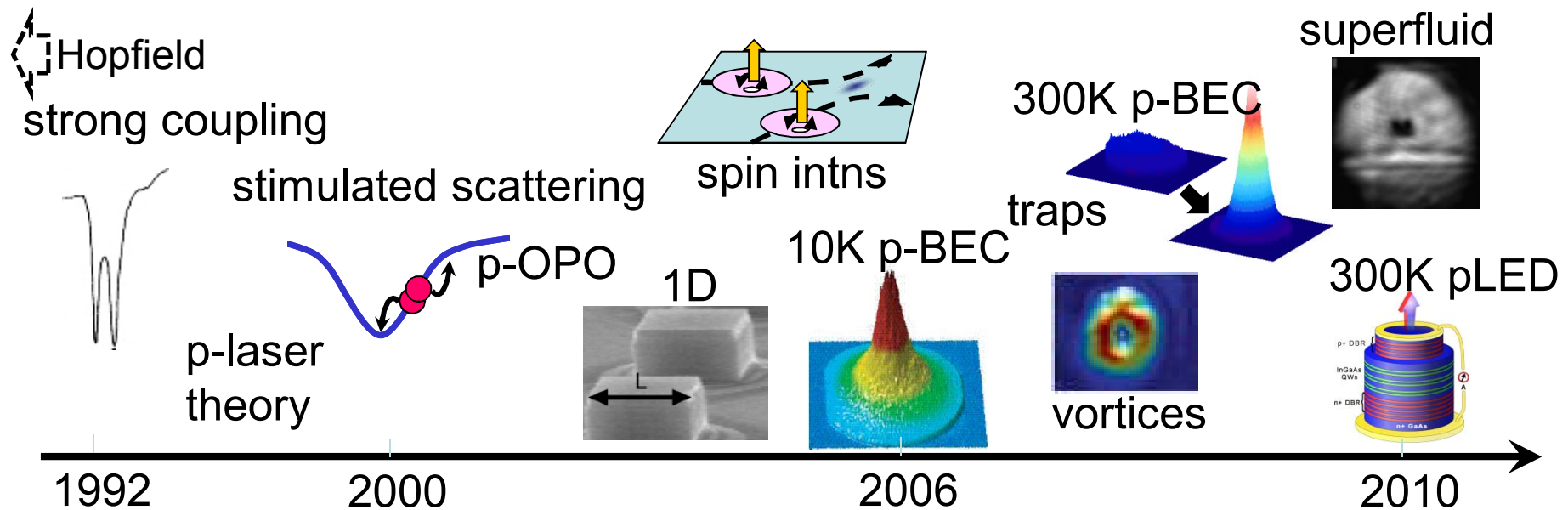


Polaritons accumulate in the lowest energy state by bosonic final state stimulation.

The coherence of the condensate builds up from an incoherent equilibrium reservoir and the BEC phase transition takes place.

The condensate emits spontaneously coherent light without necessity for population inversion

Polaritonics



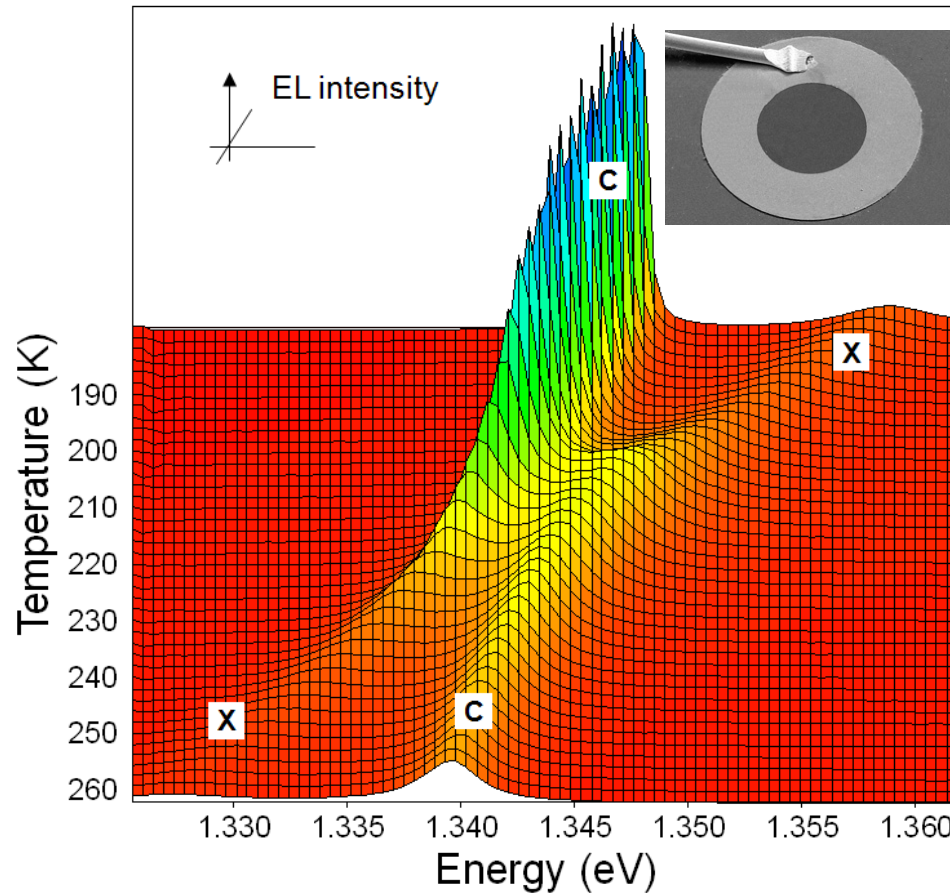
From a device perspective:

- Near speed of light lateral transport
- Light effective mass
- Condensate regime readily available on a chip even at RT

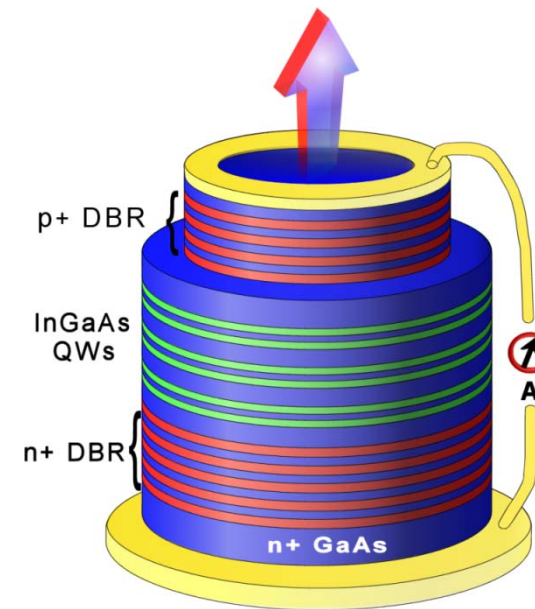
New directions: electrically driven polariton devices

Room temperature Polariton LED

Emission collected normal to the device



- Clear anticrossing observed
- Direct emission from exciton polariton states



- Rabi splitting of 4.4 meV at 219 K

Transport driven device

S. Tsintzos *et al.*, *Nature* 453, 372 (2008)



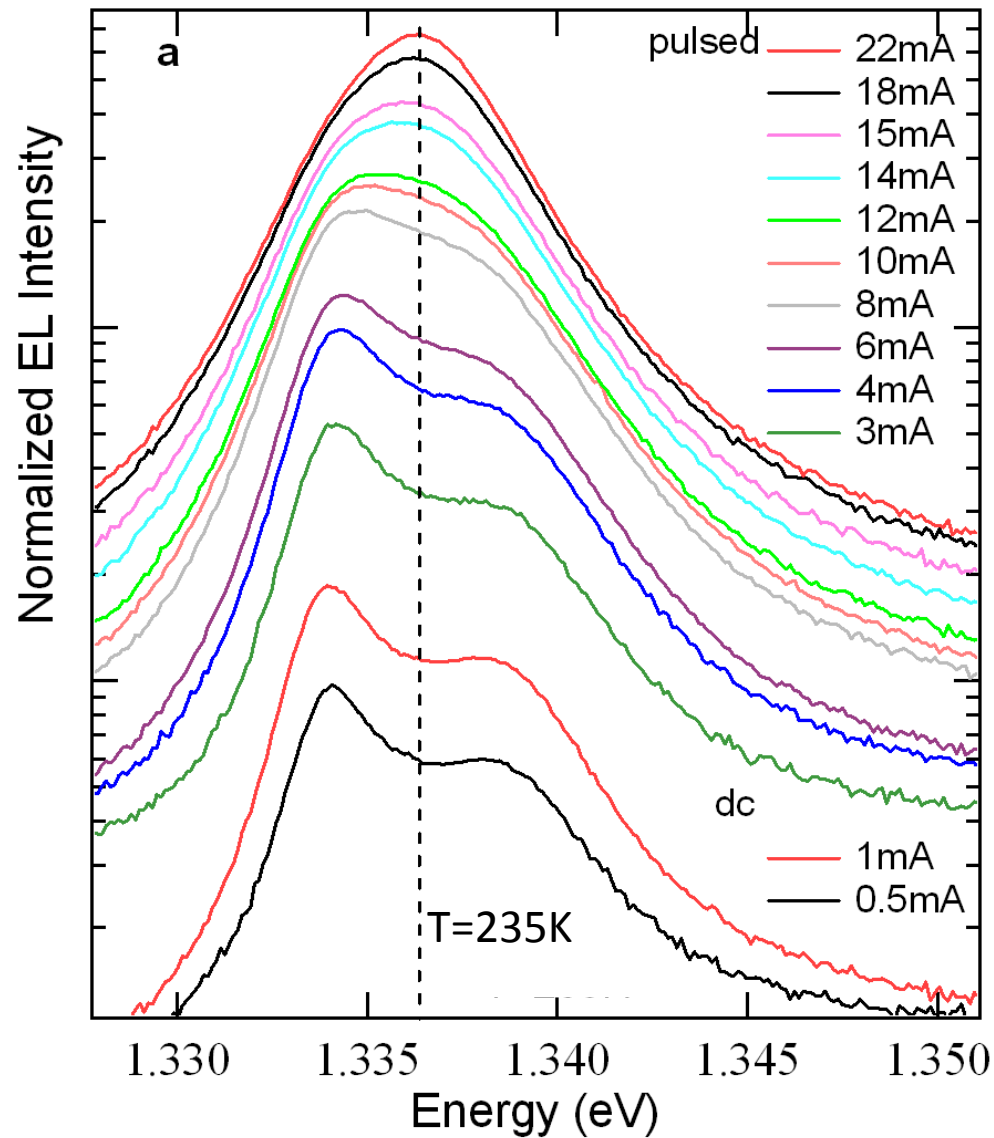
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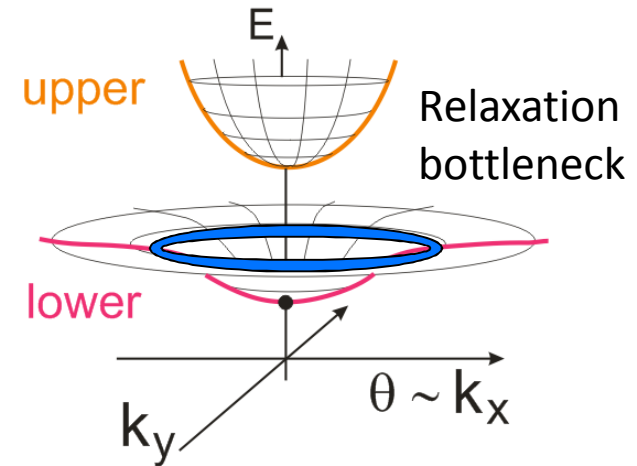
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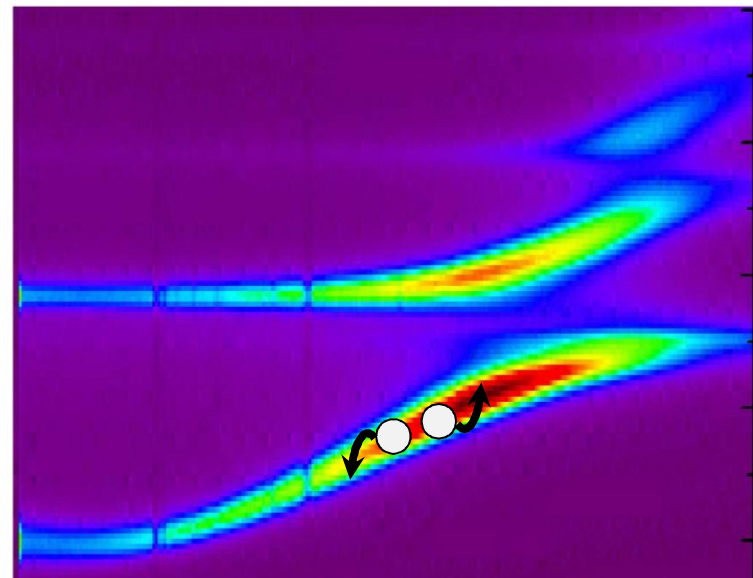
Collapse of Strong Coupling Regime at High Densities



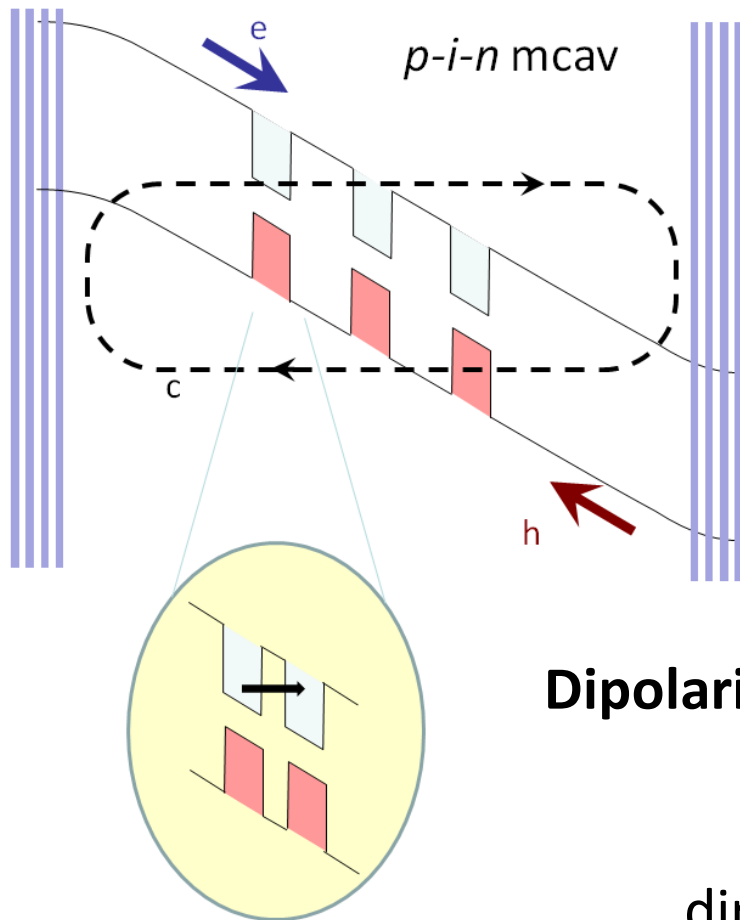
- Injection density at 22mA $\sim 10^{10}$ pol/cm²



Relaxation on lower branch governed by polariton-polariton interactions (dipole-dipole)



Electrically pumped polariton lasers



new challenges:

- strong coupling in high finesse doped microcavities structures
- injection bypassing relaxation bottleneck
- control of polariton dispersions and scatterings

Dipolariton approach: weakly-coupled double quantum wells

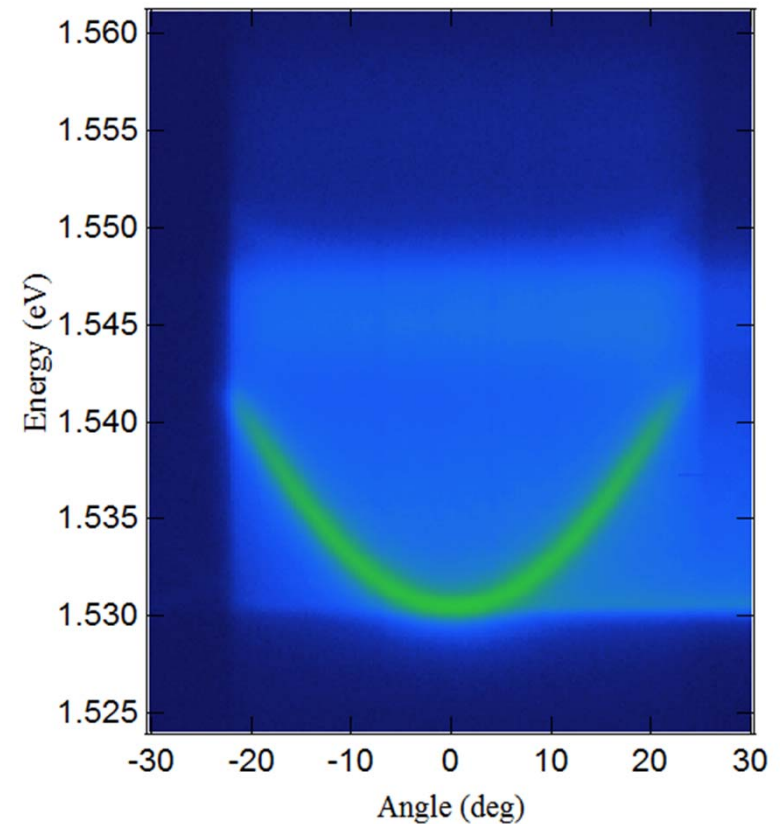
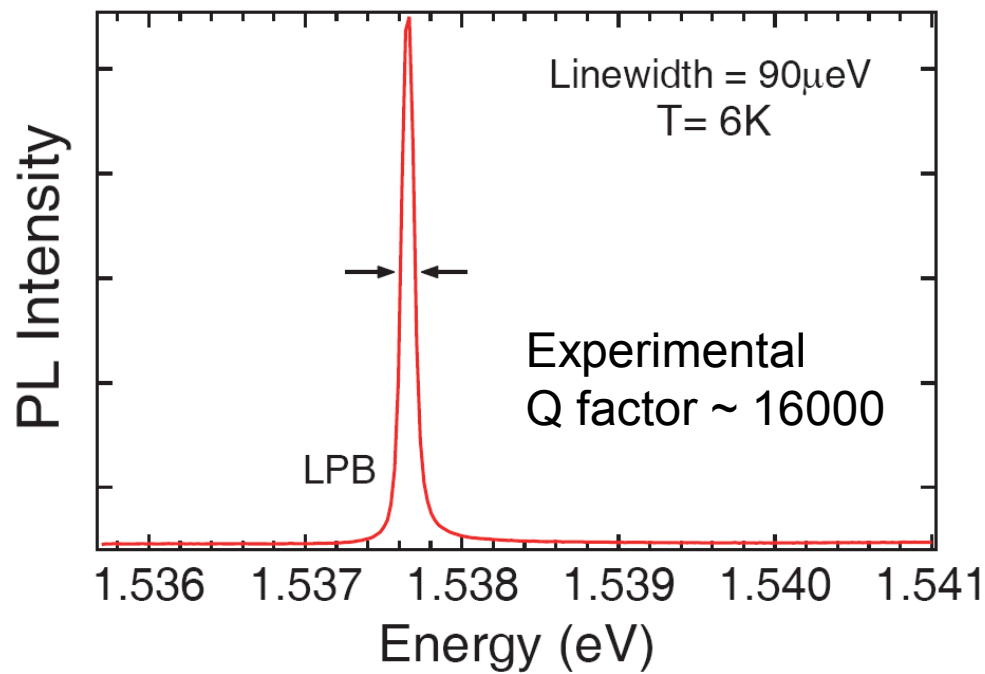


direct control of polariton dipole

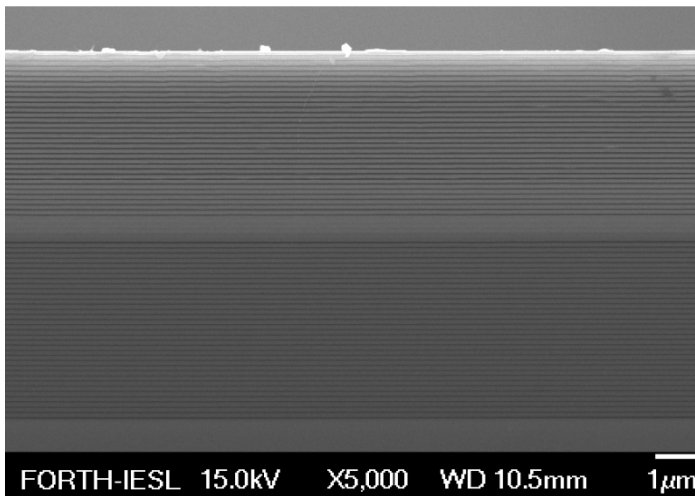
$$H_{PP}^{eff} = \frac{1}{2} \sum_{k,k',q} \frac{a_B^2}{A} \underbrace{V_{k,k',q}^{PP}} \hat{p}_{k+q}^+ \hat{p}_{k'-q}^+ \hat{p}_k \hat{p}_{k'} \quad \text{dipole-dipole}$$

Temperature Dependence of Lasing Threshold in high finesse GaAs microcavities

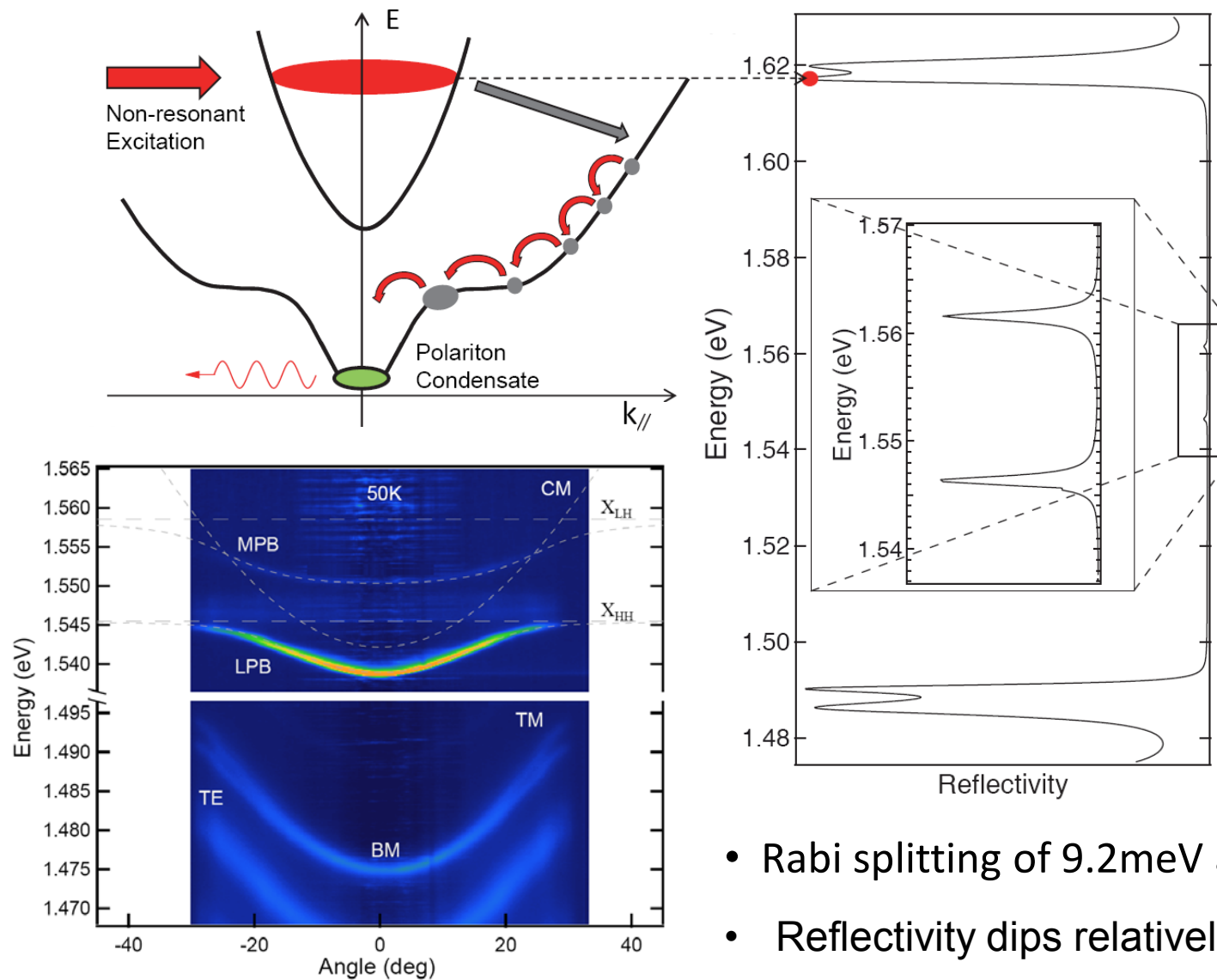
High finesse GaAs microcavity



Modeled Q factor ~ 20000



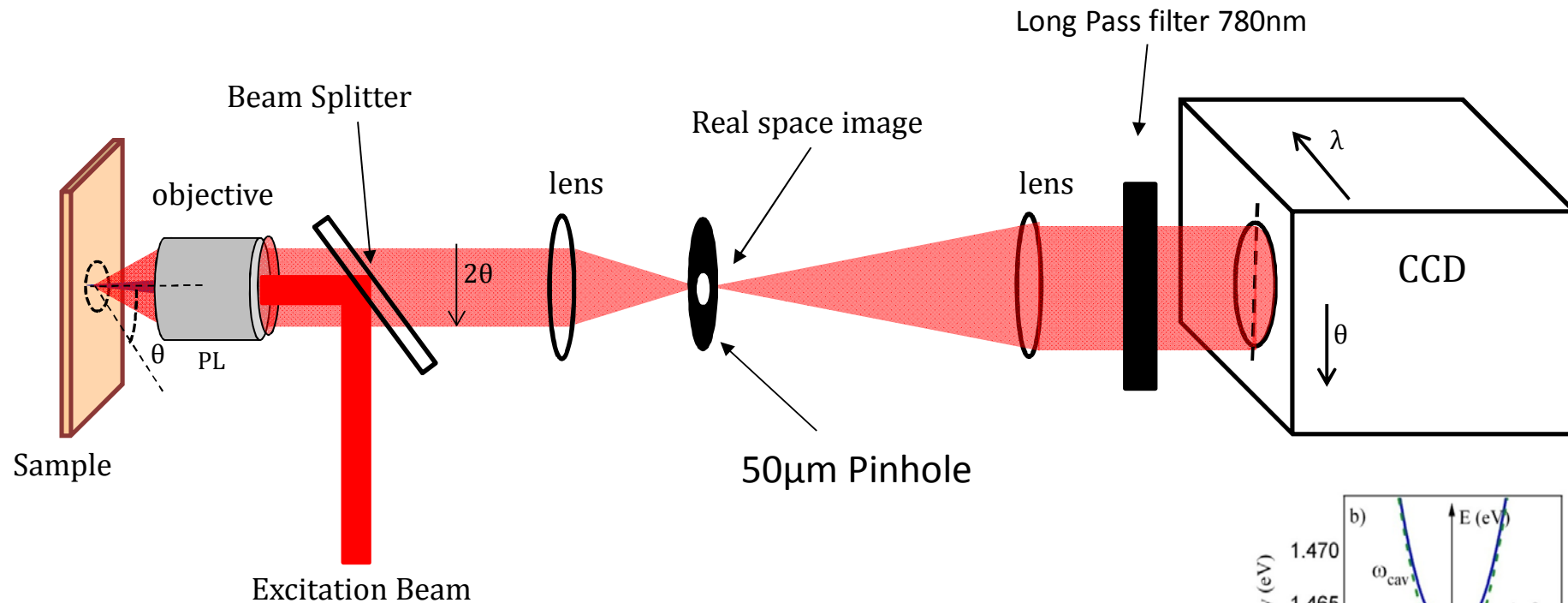
Non-resonant optical excitation



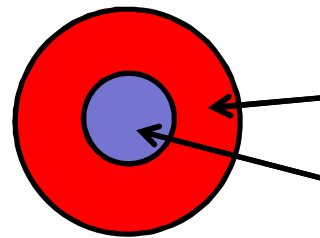
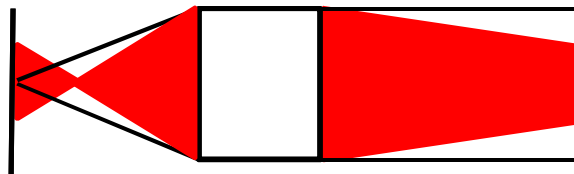
- Rabi splitting of 9.2meV at 50K
- Reflectivity dips relatively small



PL imaging Setup

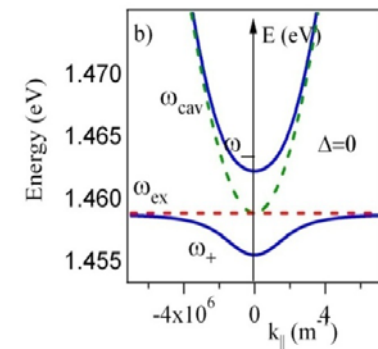


Collection of light from a very small part of excited area



Excitation spot $\sim 40\mu\text{m}$

Collection spot $\sim 5\mu\text{m}$



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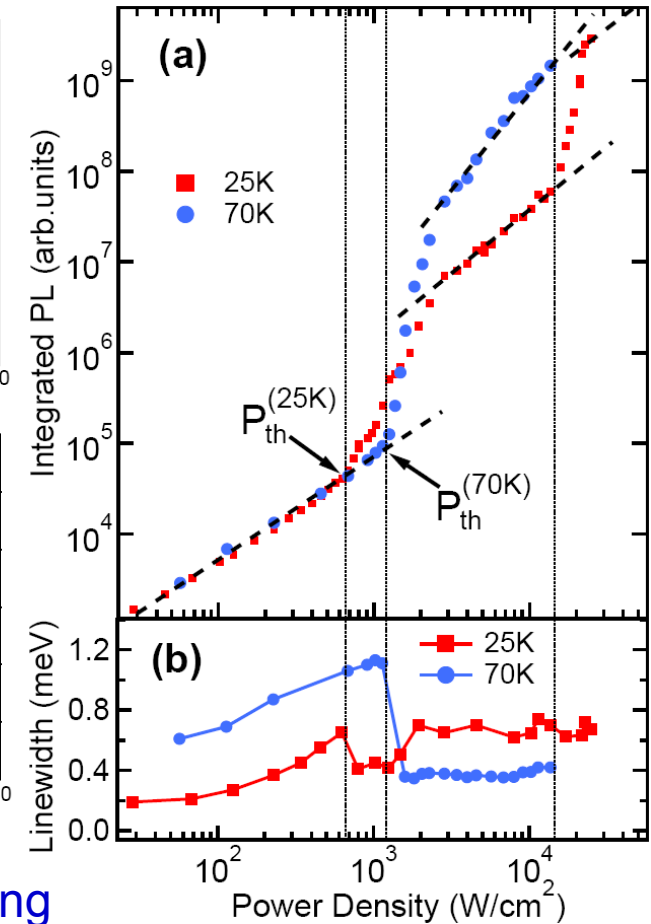
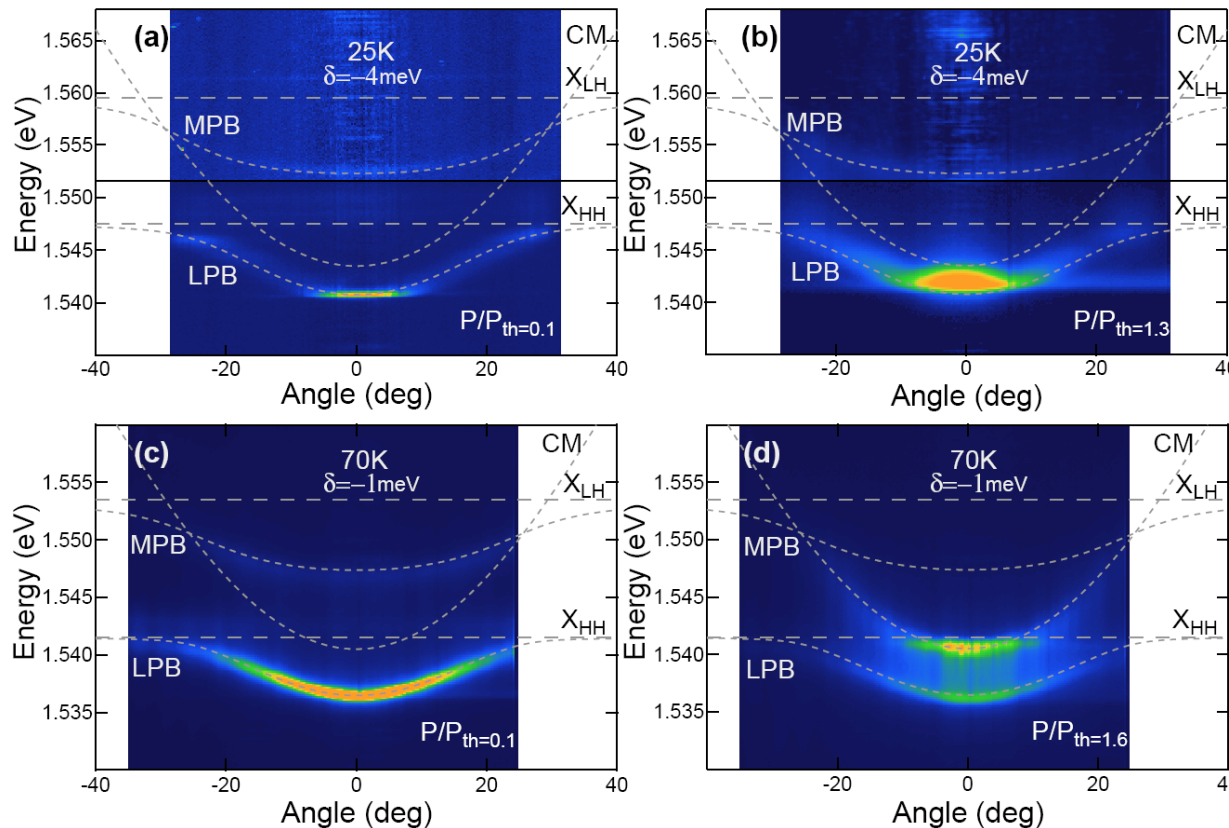
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GaAs Polariton Laser 25K vs 70K

- Nonresonant optical pumping above stopband



- Lowest Threshold at 25K ~ 6.5mW strong coupling
at 70K ~ 13mW weak coupling
- Lasing threshold only **doubles** between polariton laser at 25K and photon laser at 70K

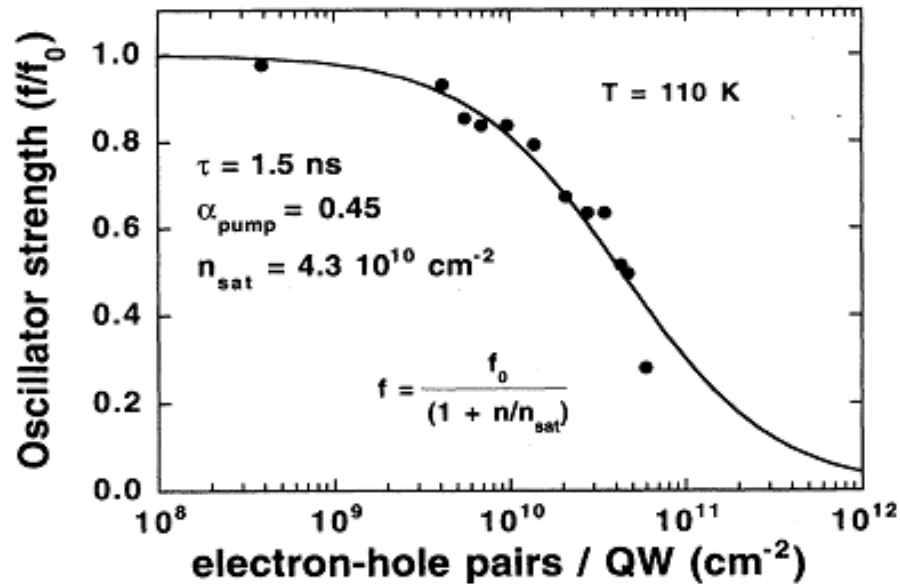
Rabi Splitting vs Density

$$\Omega = \sqrt{4V^2 - (\gamma_X - \gamma_C)^2}$$

$$\hbar V = \hbar \sqrt{\frac{1 + \sqrt{R}}{\sqrt{R}}} \frac{c\Gamma_0}{n_{cav} L_{eff}}$$

$$\Gamma_0 = \frac{e^2}{4\epsilon_0 n_{cav} m_0 c} \frac{f}{S}$$

$$f = \frac{f_0}{1 + \frac{n}{n_{sat}}}$$

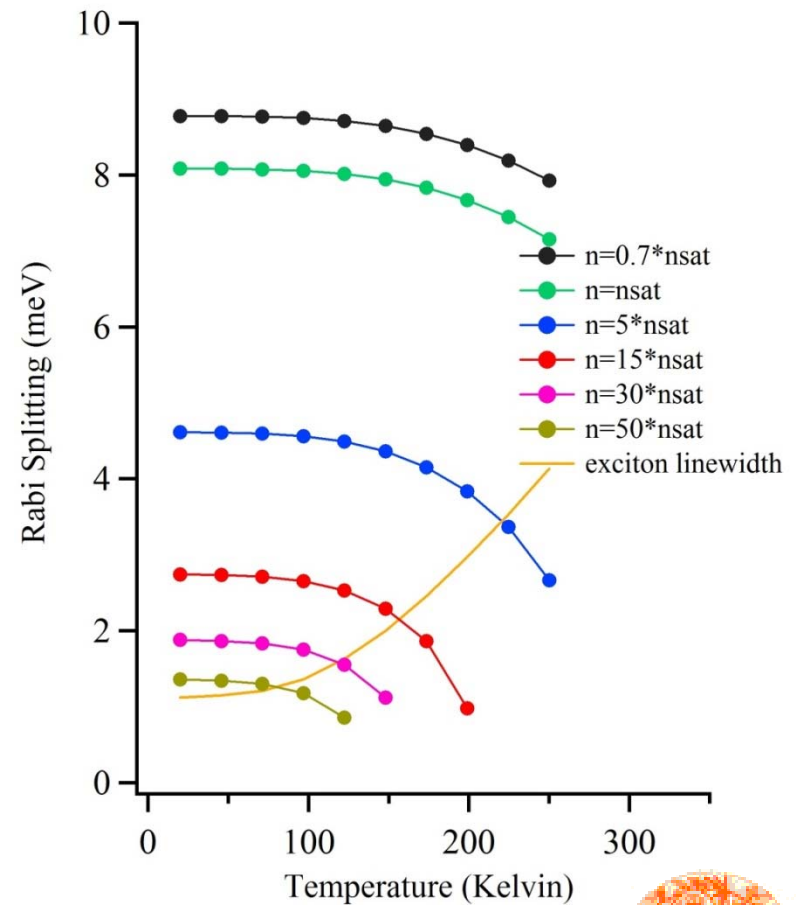


(PRB, M. Ilegems)

f : exciton oscillator strength

n : carrier density

n_{sat} : saturation density



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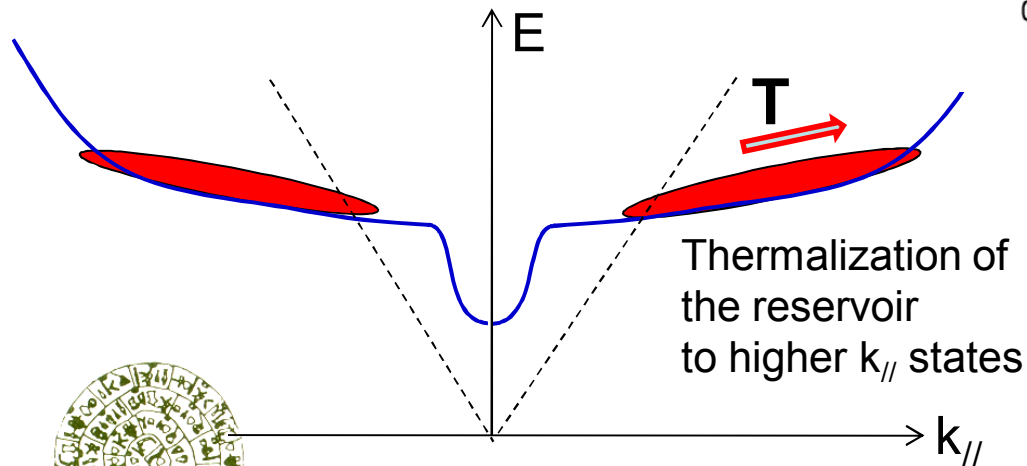
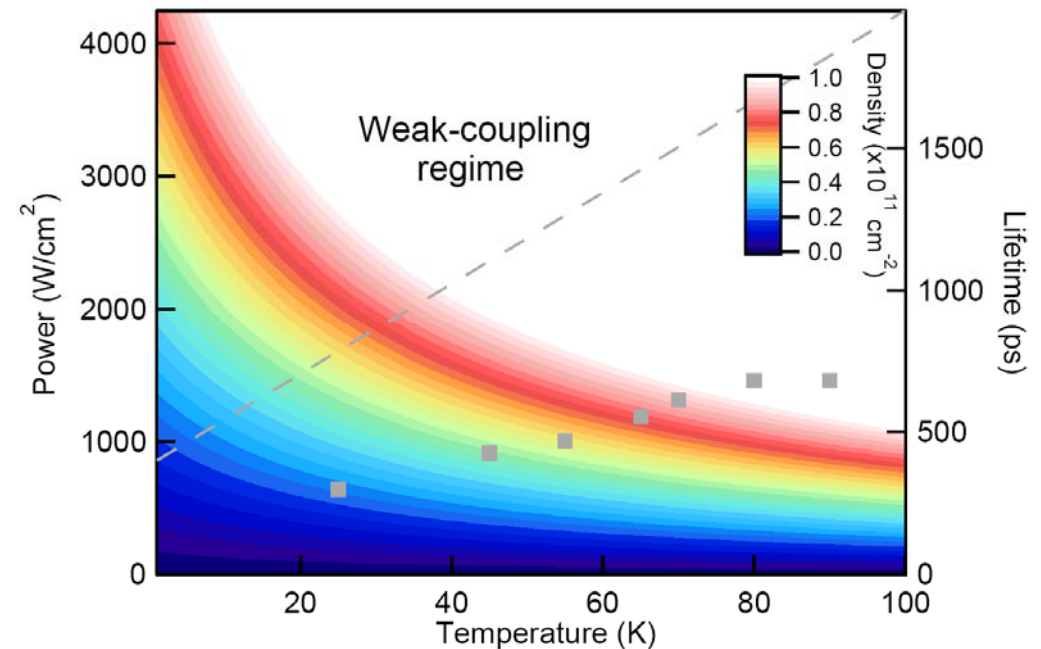
Crossover from Strong to Weak coupling Lasing

$$\frac{dN}{dt} = g - \frac{N}{\tau} \Rightarrow N = g \cdot \tau \quad (\text{steady state})$$

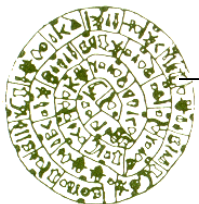
↑
pump

Exciton lifetime τ increases with temperature (PRB M.Gurioli, V. Savona)

- For same pumping rate carrier density increases dramatically with increasing T



P. Tsotsis et al.,
New Journal of Physics **14**, 023060 (2012)



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Polariton Condensate Transistor Switch

Polariton Condensate Transistor Switch

Motivation: Although photonic circuits have been proposed, a viable optical analogue to an electronic transistor has yet to be identified as switching and operating powers of these devices are typically high

Common perception: In the future, charged carriers have to be replaced by information carriers that do not suffer from scattering, capacitance and resistivity effects

Approach: Polaritons being hybrid photonic and electronic states offer natural bridge between these two systems

Excitonic component allows them to interact strongly giving rise to the nonlinear functionality enjoyed by electrons

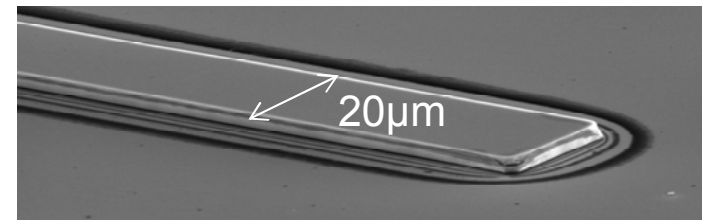
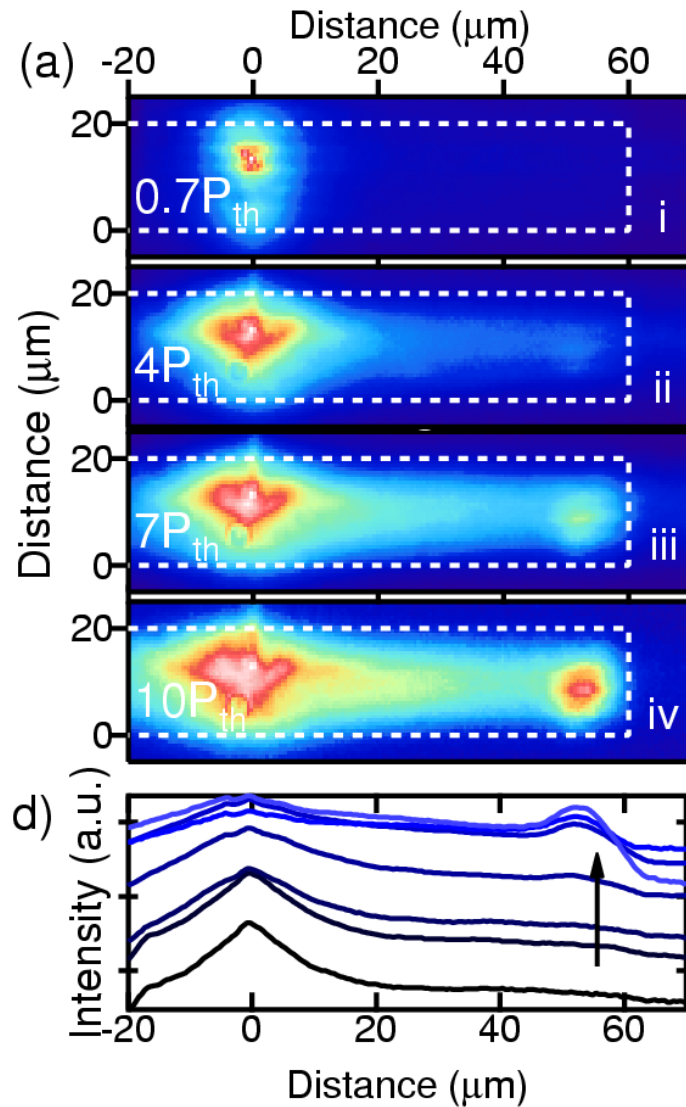
Photonic component restricts their dephasing allowing them to carry information with minimal data loss and high speed

Macroscopic quantum properties of polariton condensates make them ideal candidates for use in quantum information devices and all optical circuits

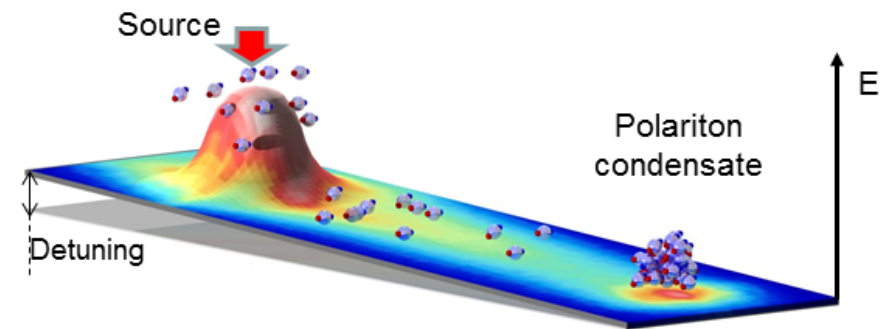
Gao et al., PRB 85, 235102 (2012)
D.Ballarini et al. arXiv:1201.4071 (2012)

D.Sanvitto *et al.* Nature Photon. 5, 610 (2011)
E.Wertz *et al.* Nature Phys 6, 860 (2010)

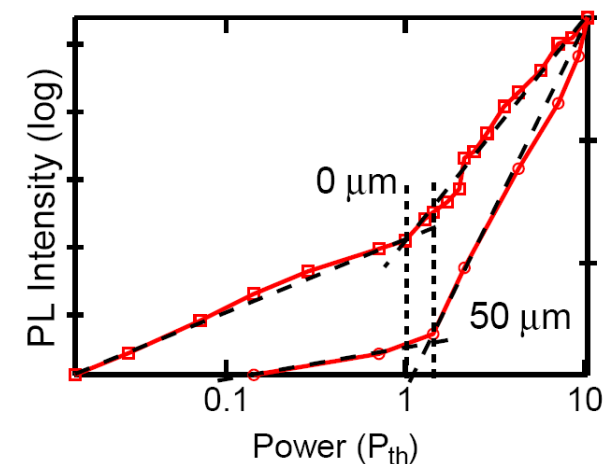
Generating Polariton Condensate Flow



Only top DBR is etched

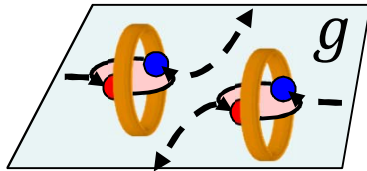


- Polariton condensate forming at the ridge end

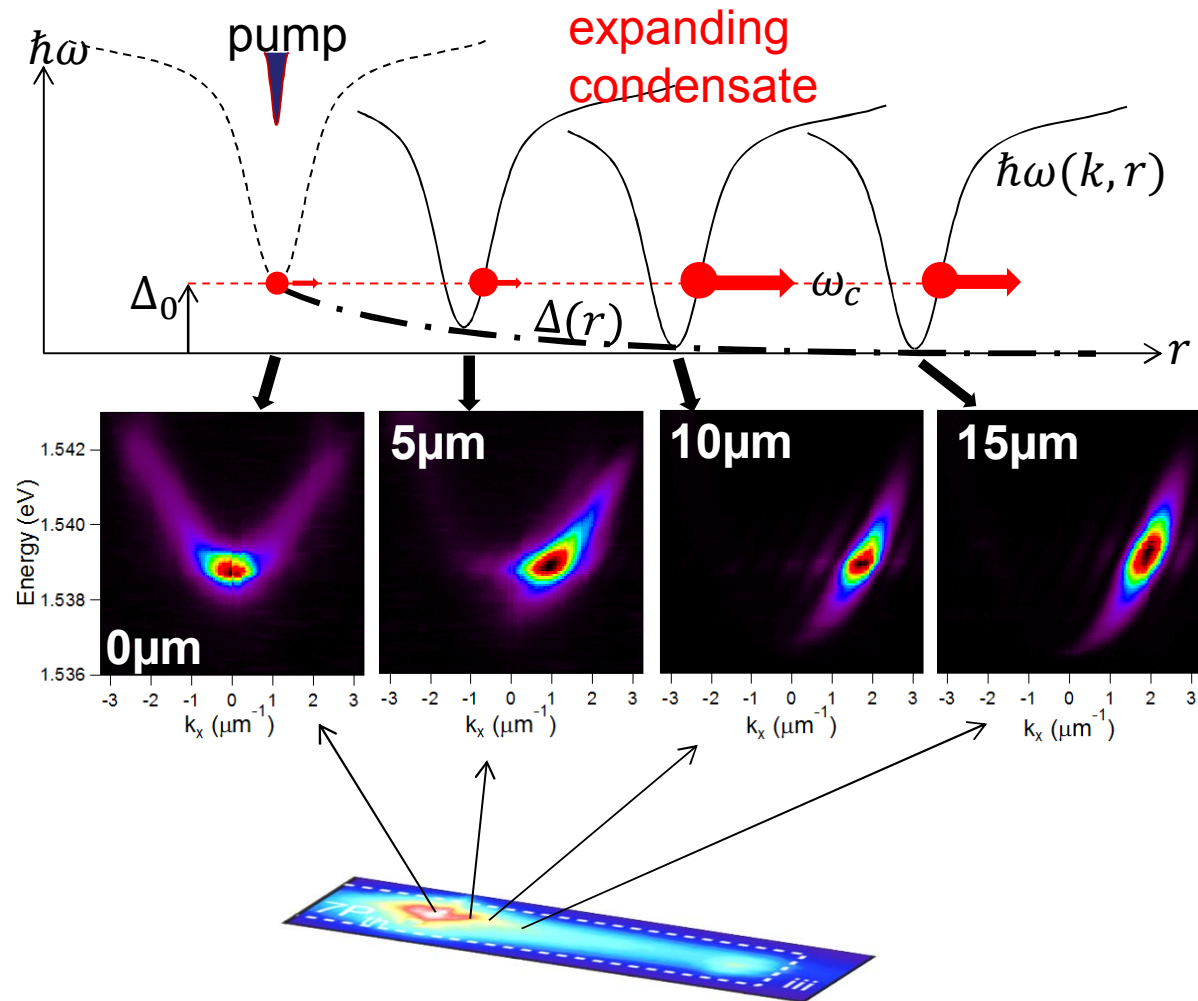
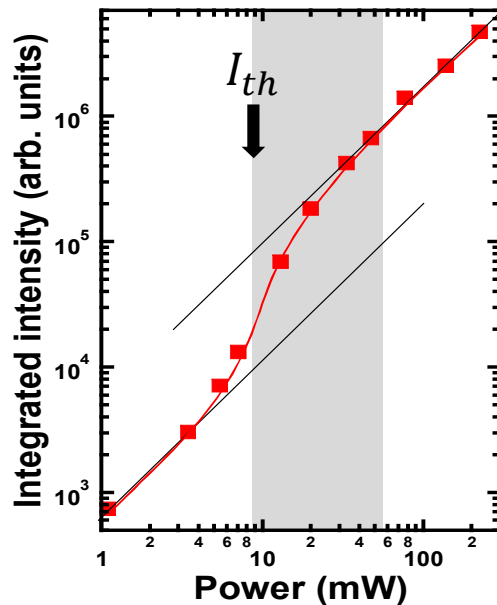


- Local pump induced blueshift and lateral confinement forces polariton flow along the ridge

Ballistic Condensate Ejection

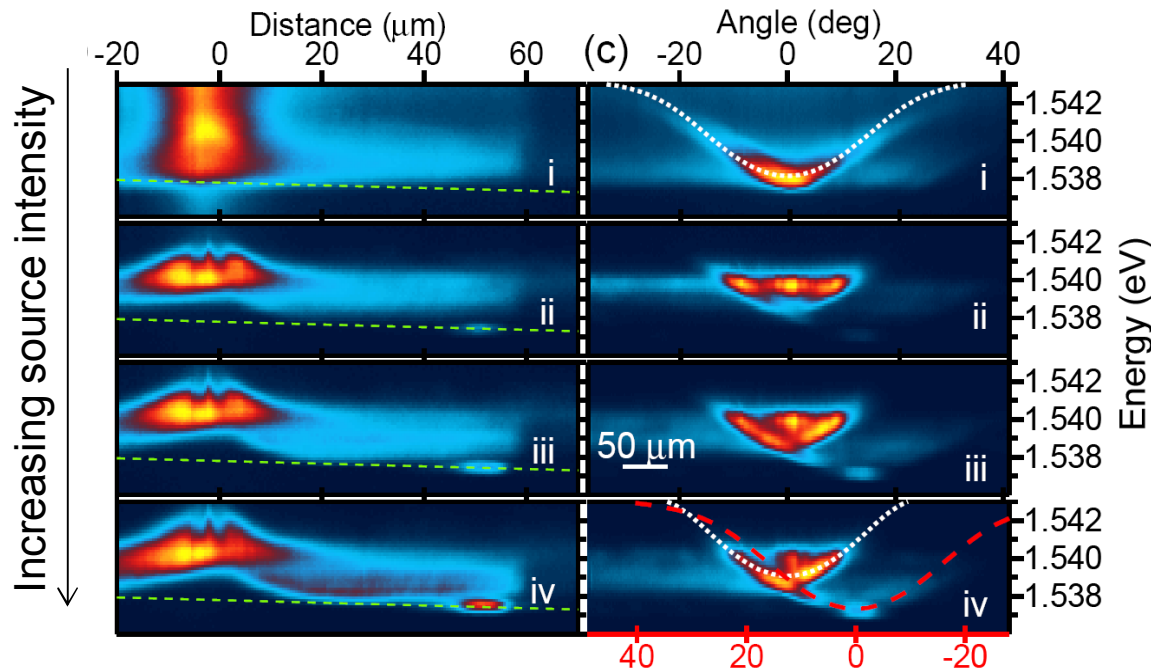


- blue shift at pump
 $V_{max} = g|\psi|^2$
- polaritons expand along the ridge

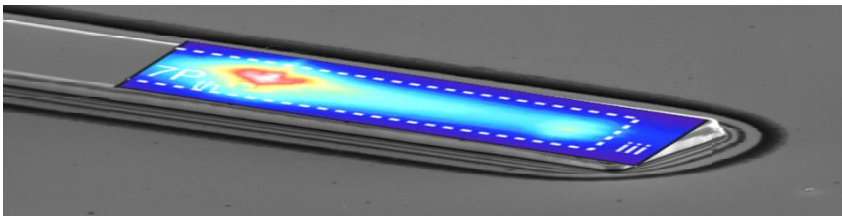
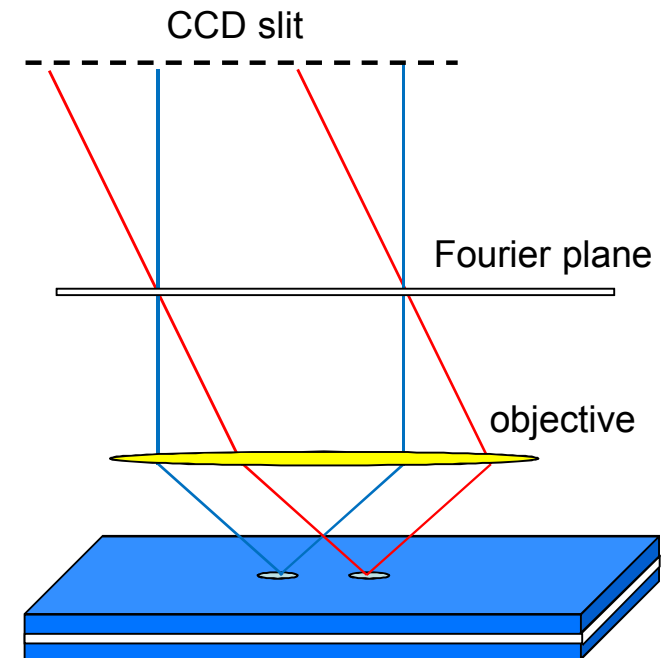


G. Christmann *et al.*, Phys. Rev. B 85, 235303 (2012)

Polariton Condensate Built-up



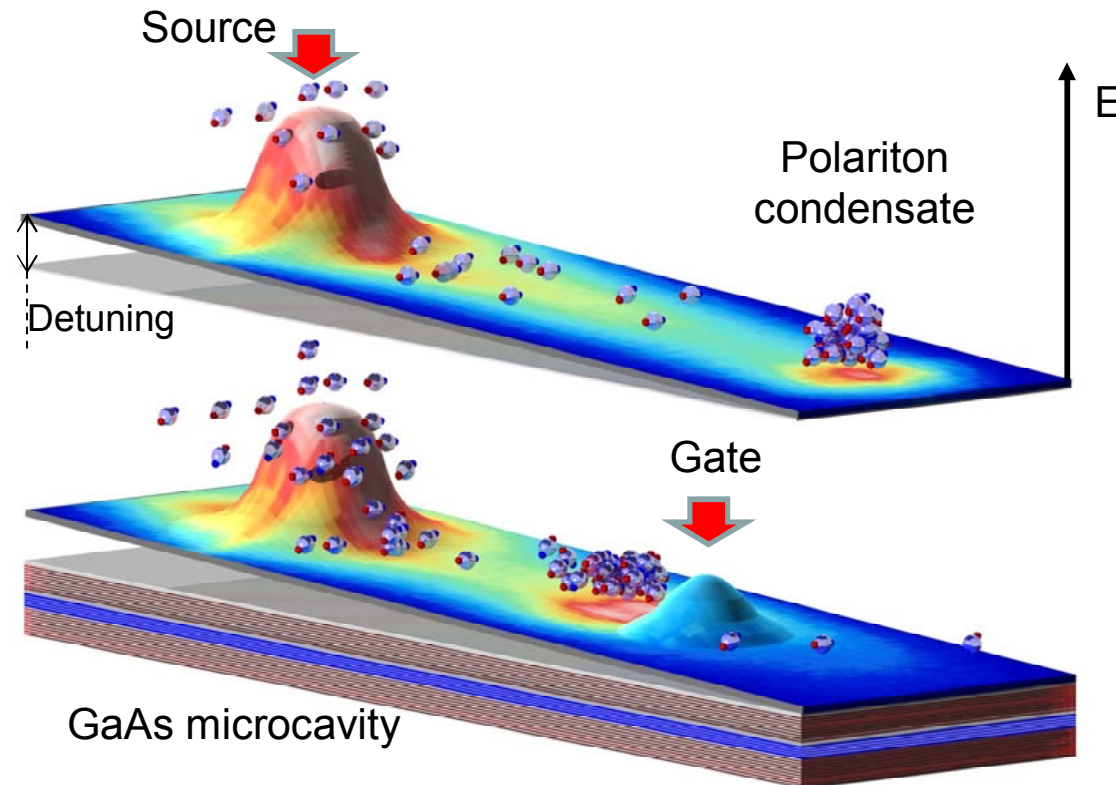
- spatially separated and angle resolved emission



- Ballistic transport of polaritons
- Polaritons flow and relax in the direction of negative detuning
- Condensate forming at the ridge end

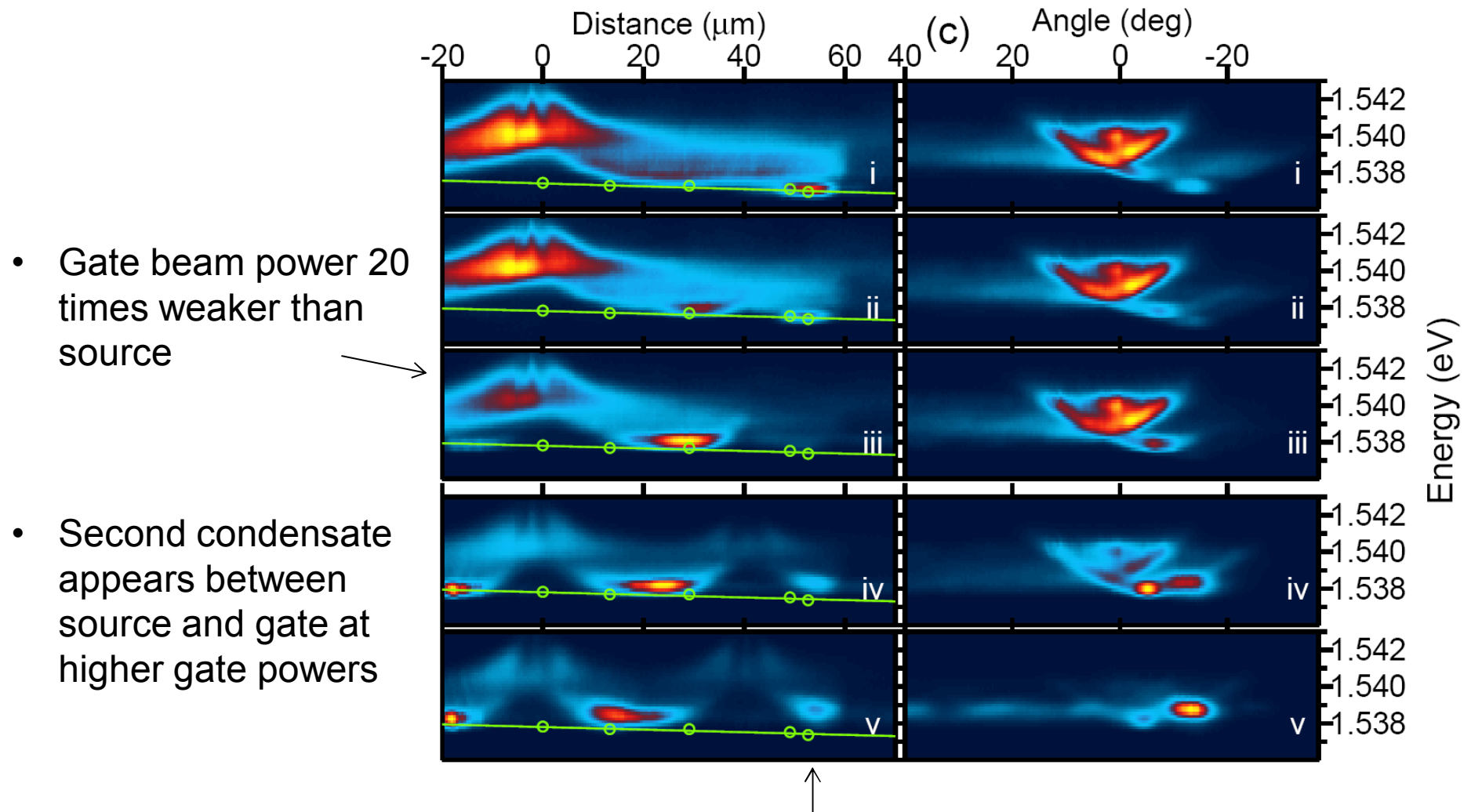


Polariton Condensate Transistor Switch



- Polariton propagation is controlled using a second weaker beam that gates the polariton flux by modifying the energy landscape

Gating Polariton Condensate Flow

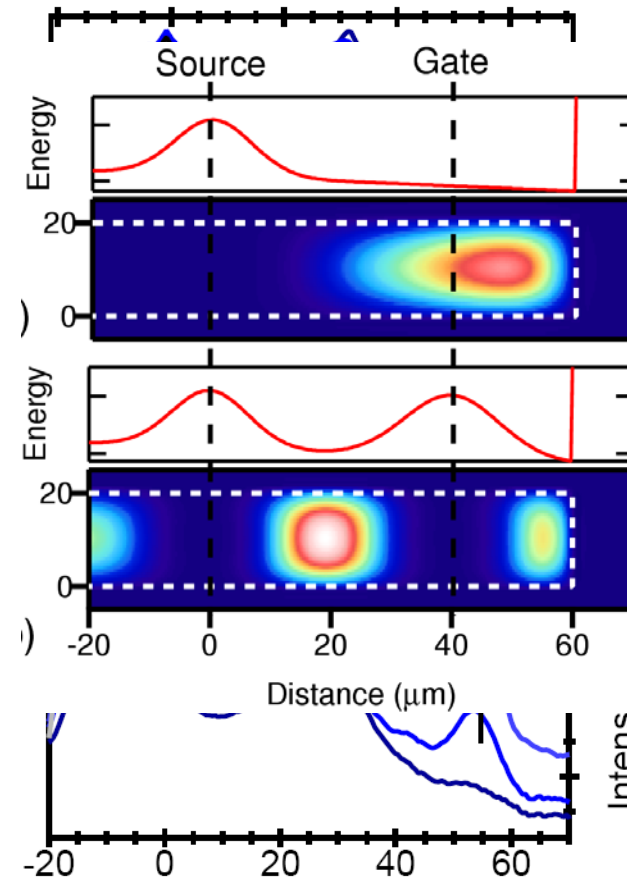
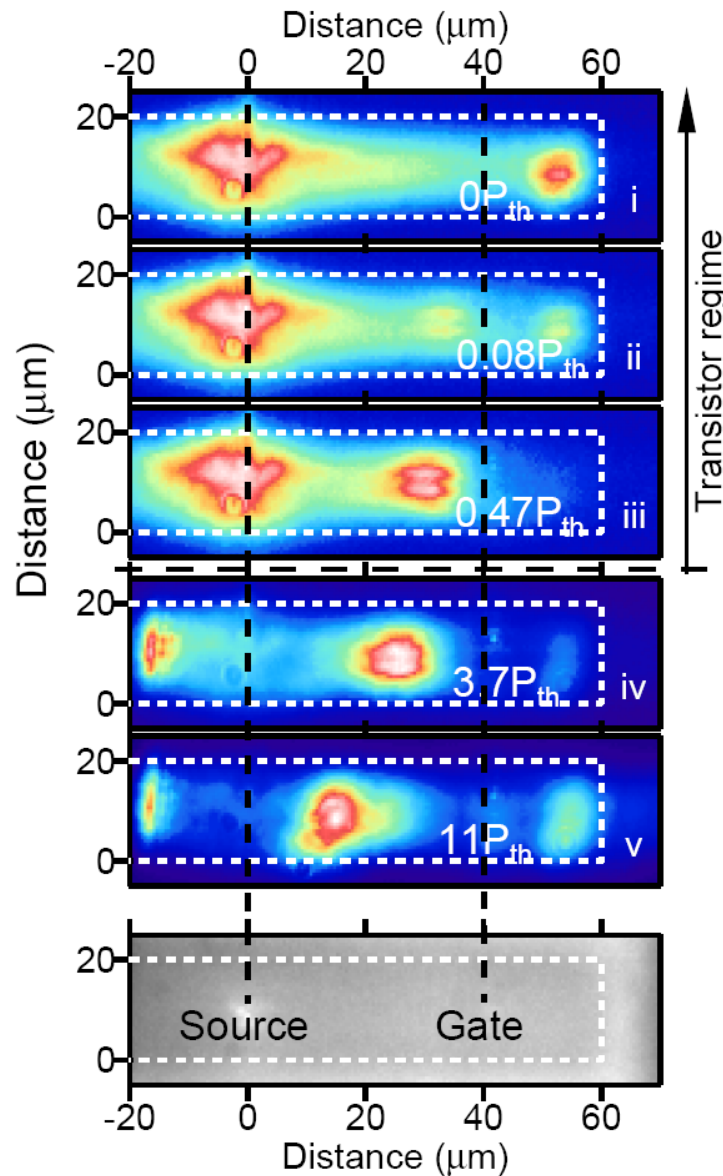


- Gate beam power 20 times weaker than source

- Second condensate appears between source and gate at higher gate powers

- At higher powers gate re-pumps the condensate at the ridge end

Gating Polariton Condensate Flow



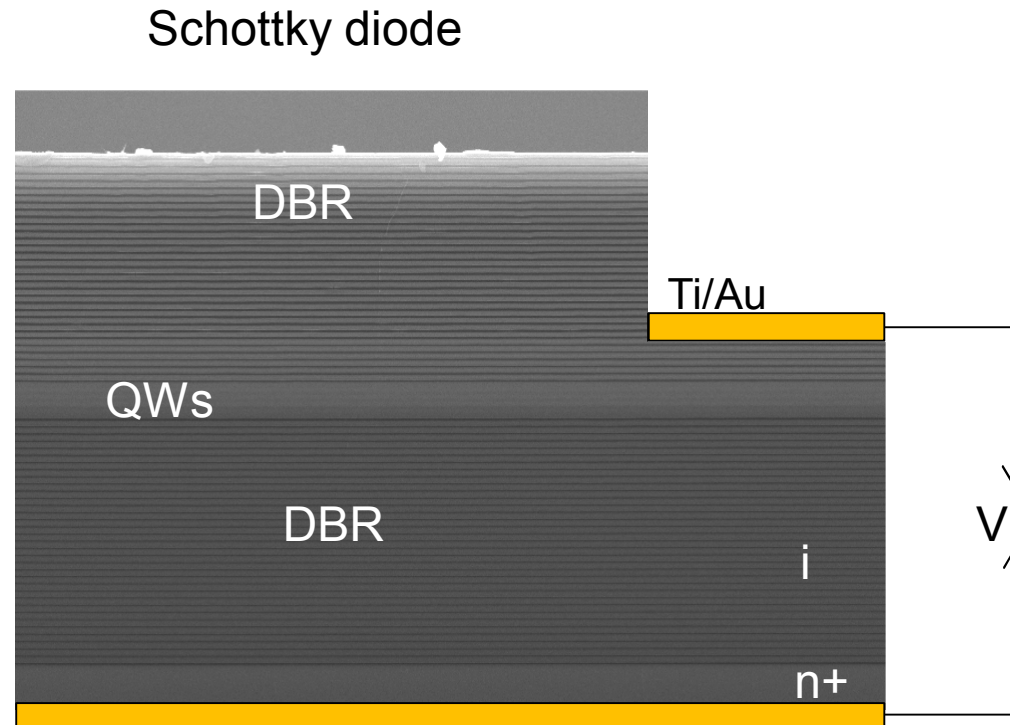
Theoretical modeling by Tim Liew

- gating efficiency up to 90% is demonstrated

Electrical and optical control of polariton condensates

Is electric gating of transistor feasible ?

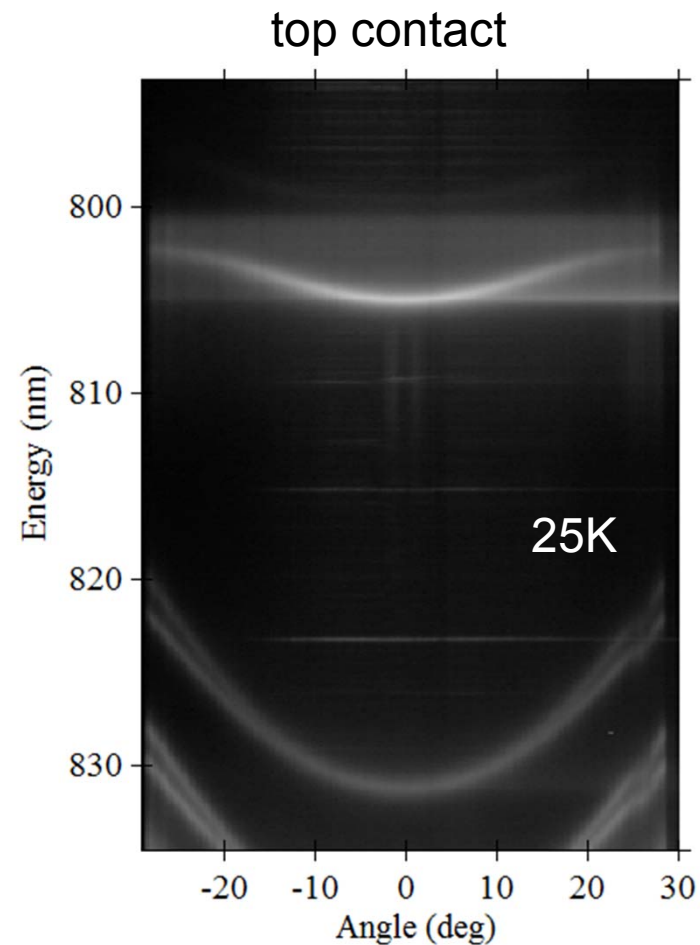
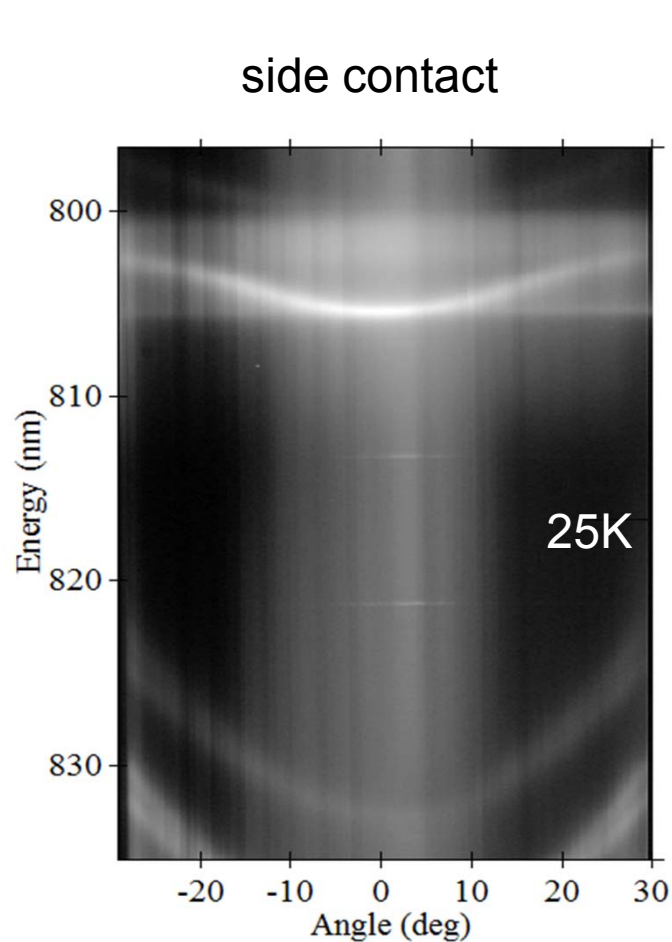
Electrical control of polariton dispersions



- Application of electric field to the QW tunes the exciton energy through QCSE
- Reduction in exciton oscillator strength & Rabi splitting have to be considered



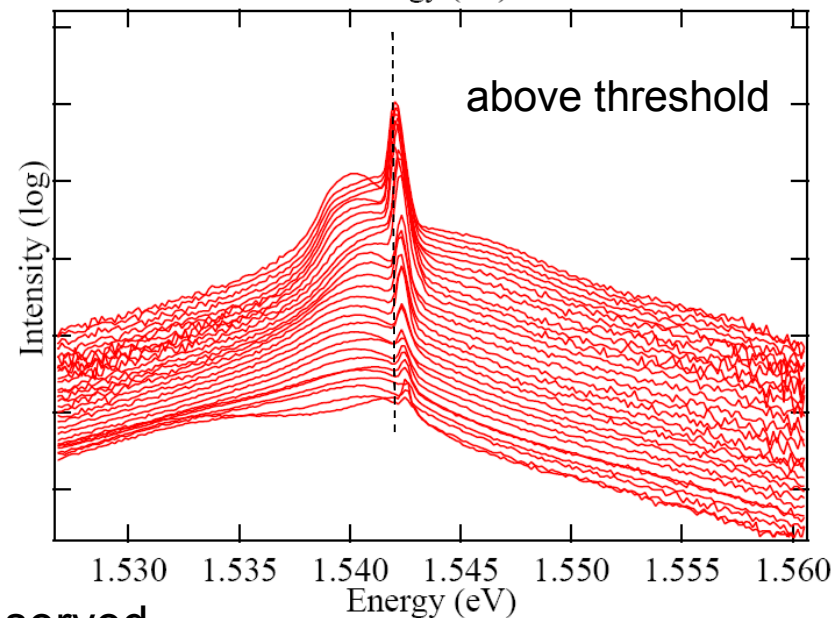
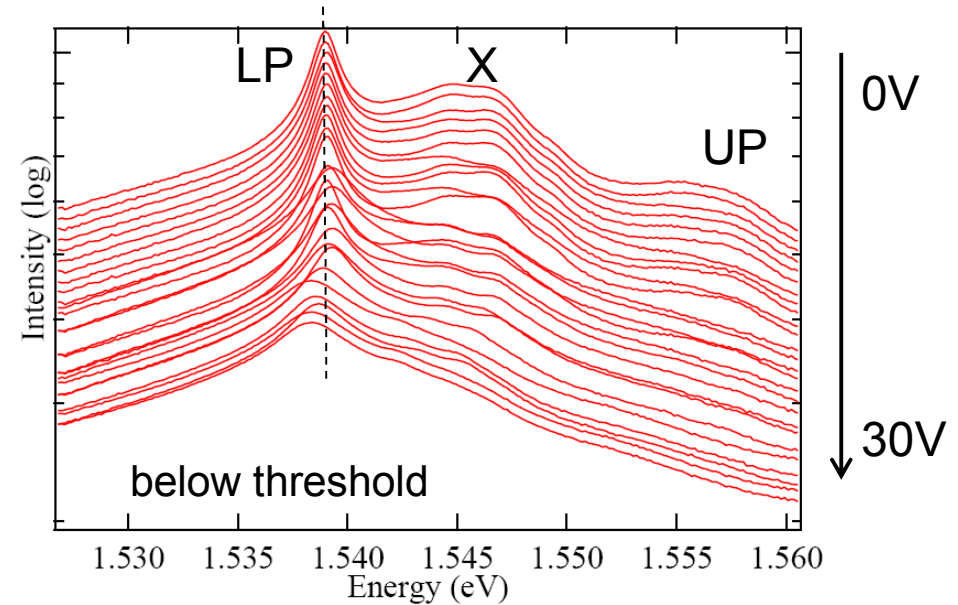
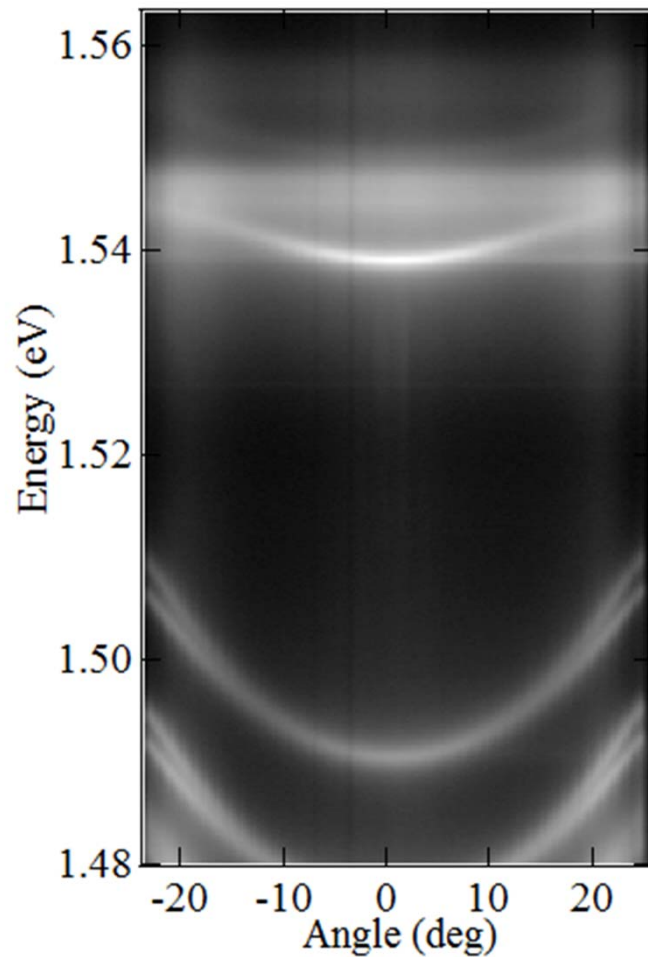
Electrical control of polariton dispersions



- Clear tuning of the lower polariton branch energy
- Schottky diode allows local spatial field to be applied

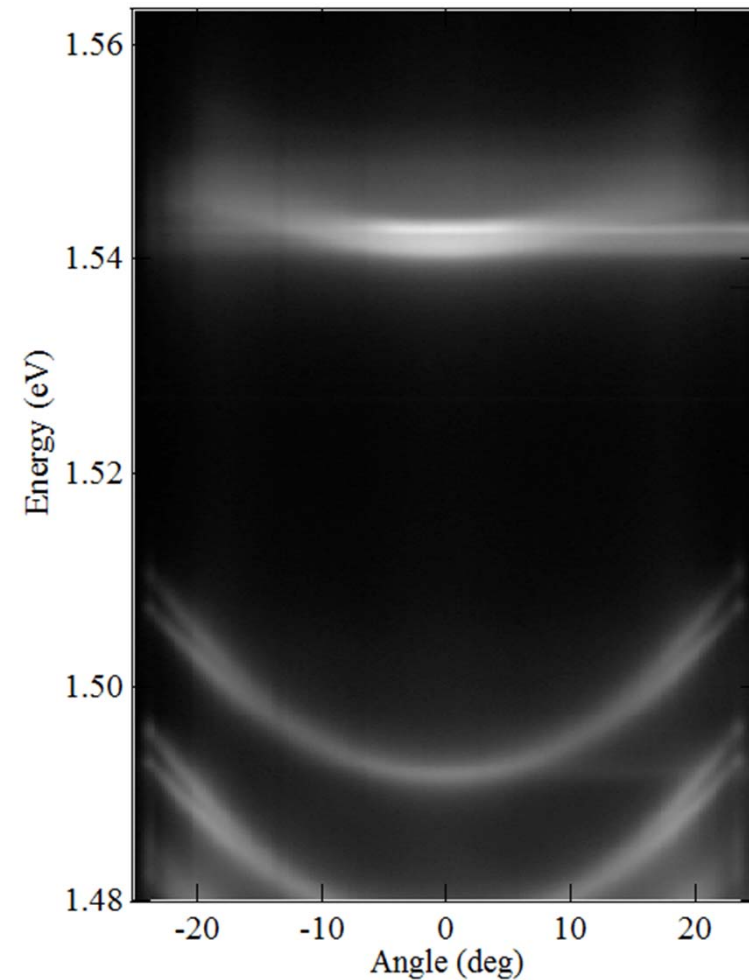
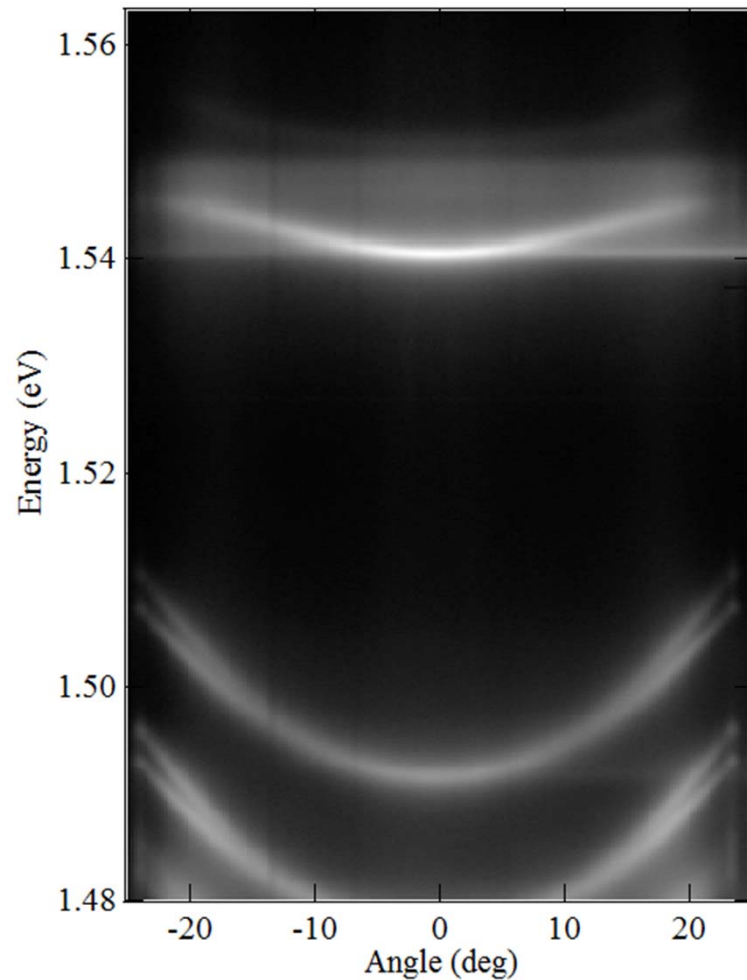


Control of polariton dispersions in nonlinear regime



- electric tuning of the lasing energy observed

Control of polariton dispersions in nonlinear regime



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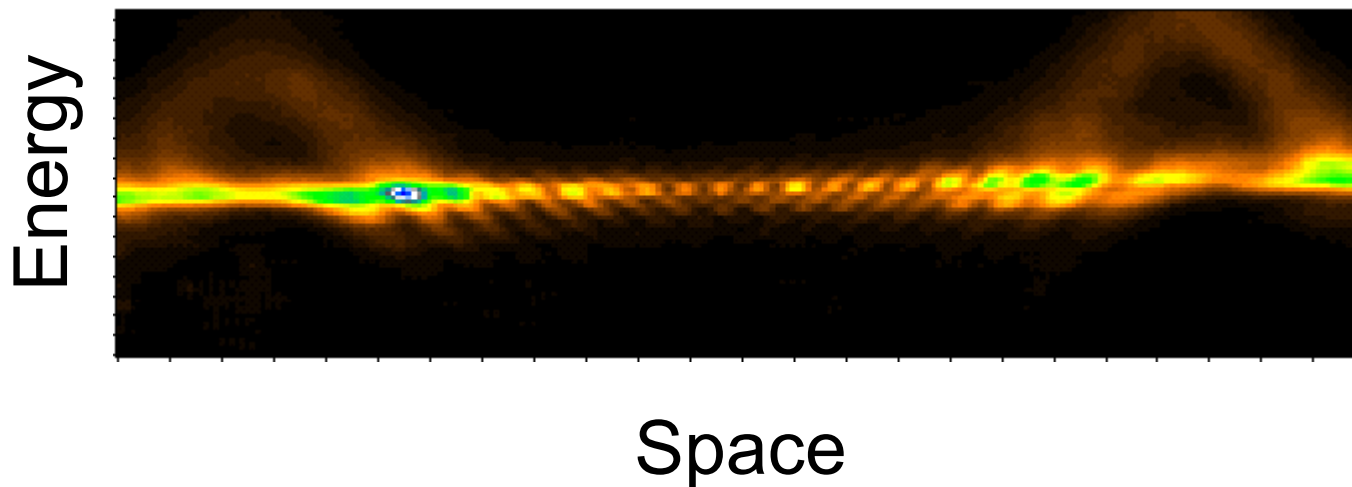
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Interactions Between Condensates

- Can we make two independent condensates interact on a chip?
- What happens if we launch two condensates against each other

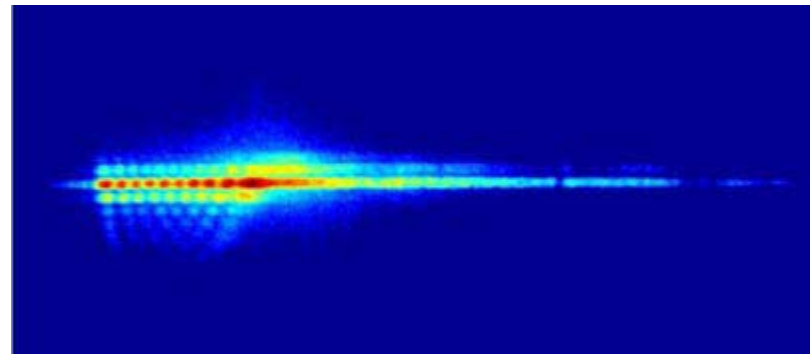


LETTERS
PUBLISHED ONLINE: 29 AUGUST 2010 | DOI: 10.1038/NPHYS1750

nature
physics

Spontaneous formation and optical manipulation of extended polariton condensates

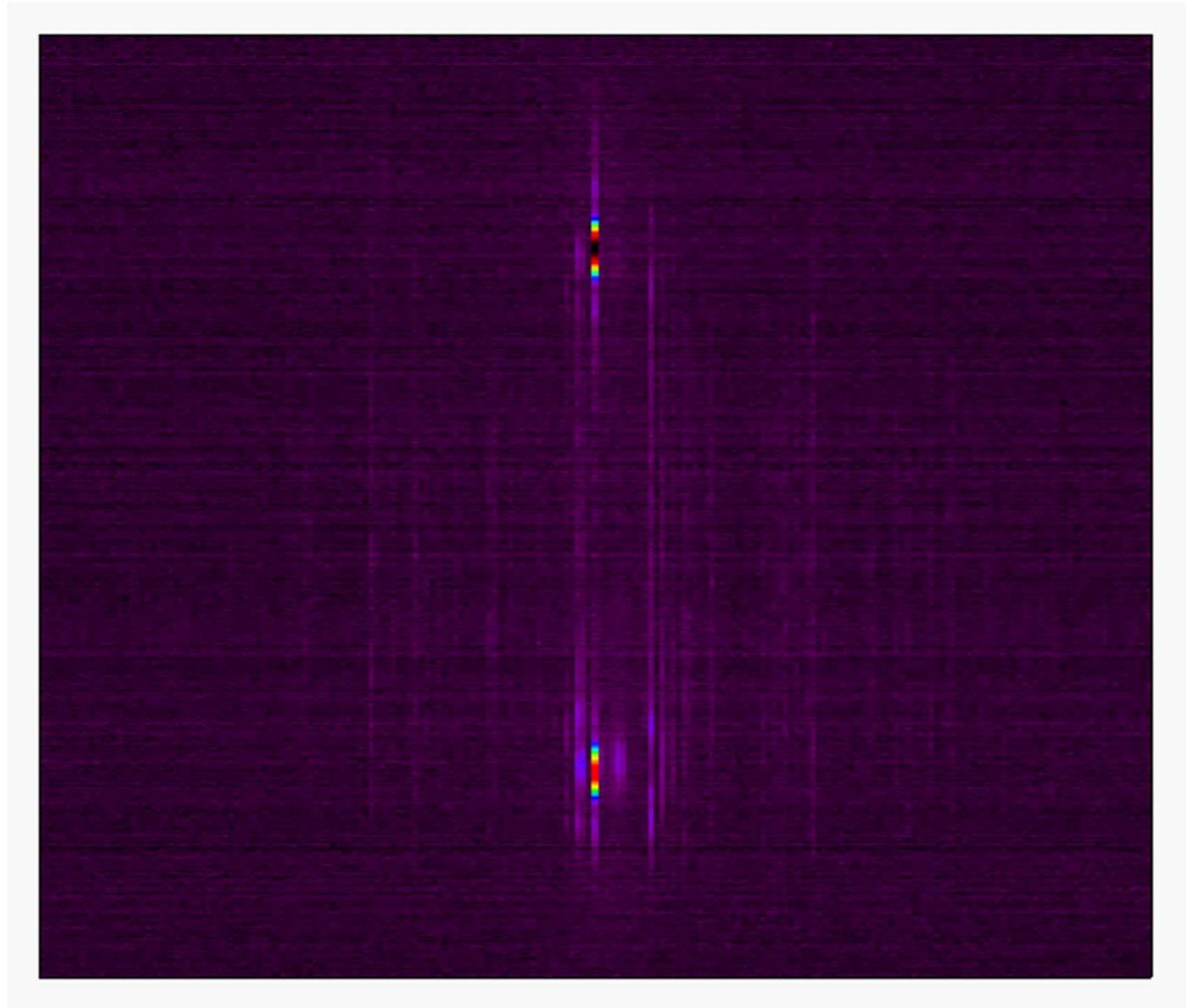
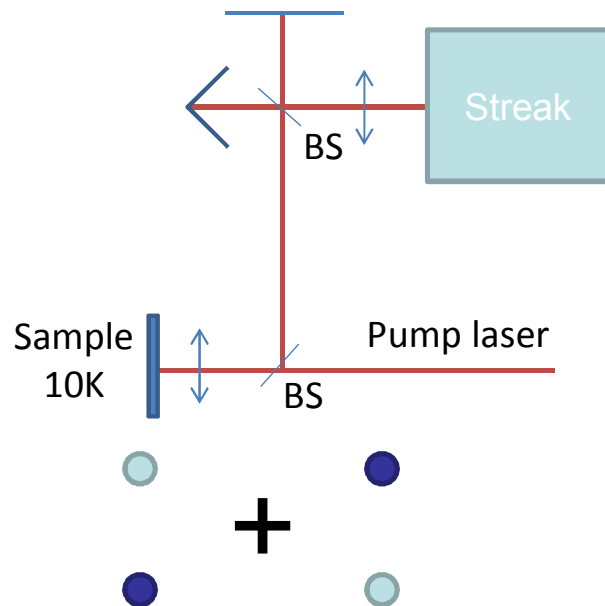
E. Wertz¹, L. Ferrier¹, D. D. Solnyshkov², R. Johne², D. Sanvitto³, A. Lemaitre¹, I. Sagnes¹,
R. Grousson⁴, A. V. Kavokin⁵, P. Senellart¹, G. Malpuech² and J. Bloch^{1*}



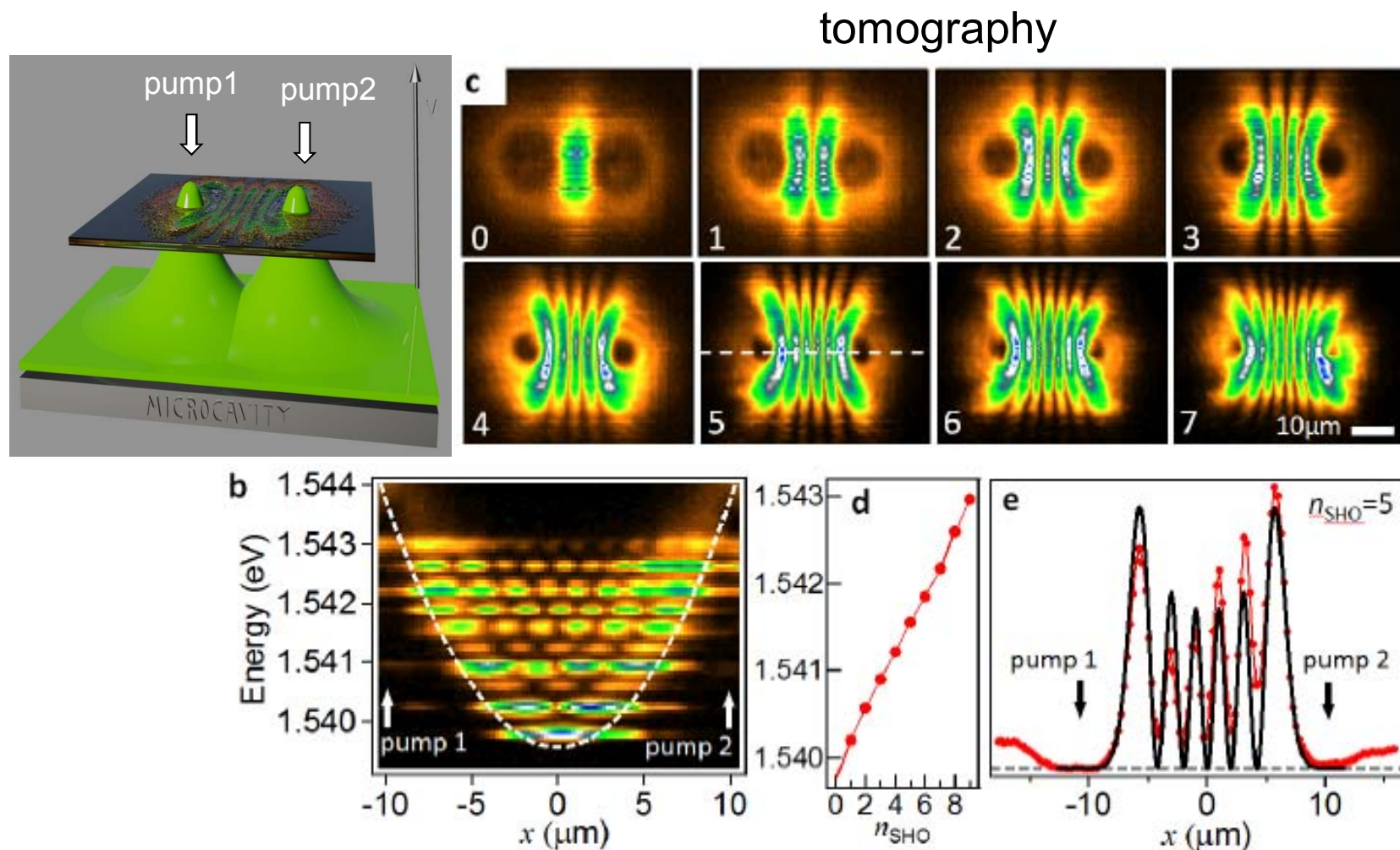
Buildup of Coherence and Phase Locking

Time resolved
measurement &
interferometry

Pulsed excitation,
interference of one with
the other



Polariton condensates in a parabolic optical trap



- equal spaced energies SHO wavefunctions
- harmonic potential - quantum pendulum

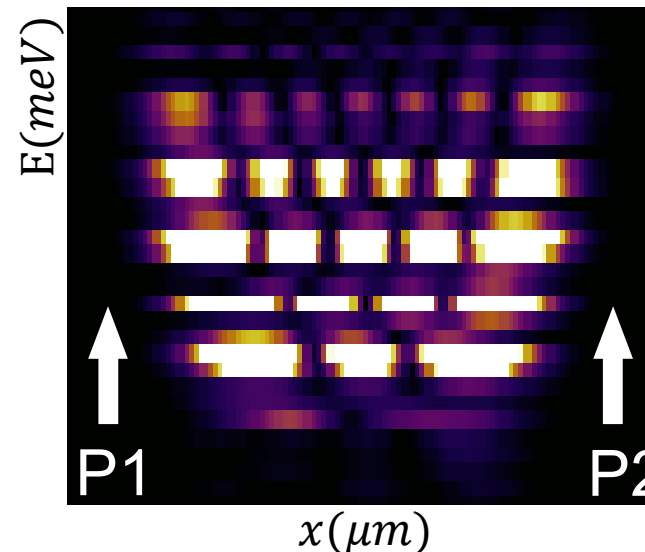
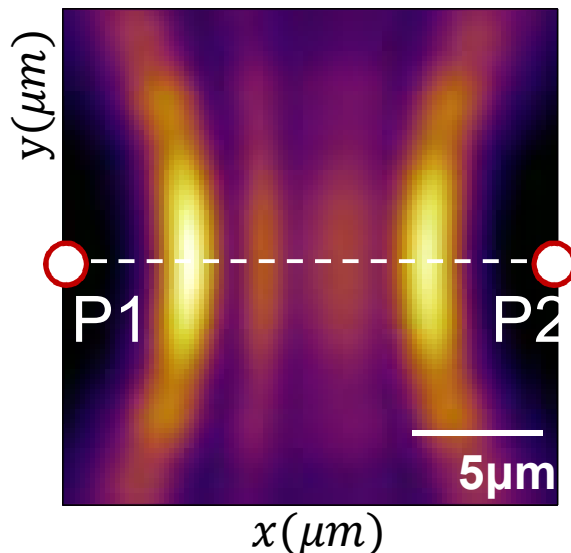
Condensate theory

- complex Ginzburg-Landau equation (cGL)

$$i\hbar\partial_t\psi = [E(i\nabla) + \overbrace{g|\psi|^2 + \hbar R_R N(\mathbf{r}, t)}^{\text{polariton potential}}]\psi + i\left[\overbrace{\frac{\hbar}{2}R_R N(\mathbf{r}, t)}^{\text{reservoir pump}} - \underbrace{i\hbar\eta N\partial_t}_{\text{relaxation}} - \overbrace{\Gamma_C}^{\text{decay}}\right]\psi$$

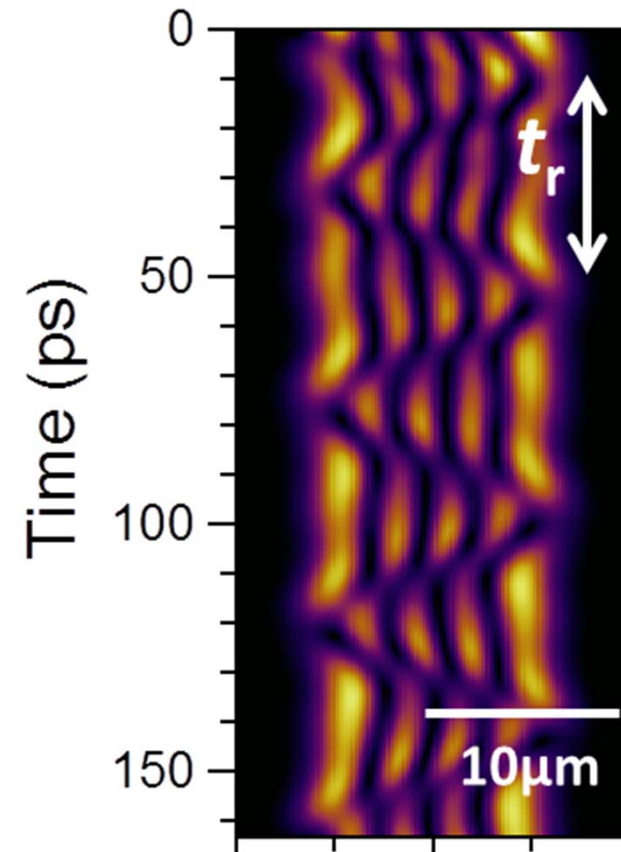
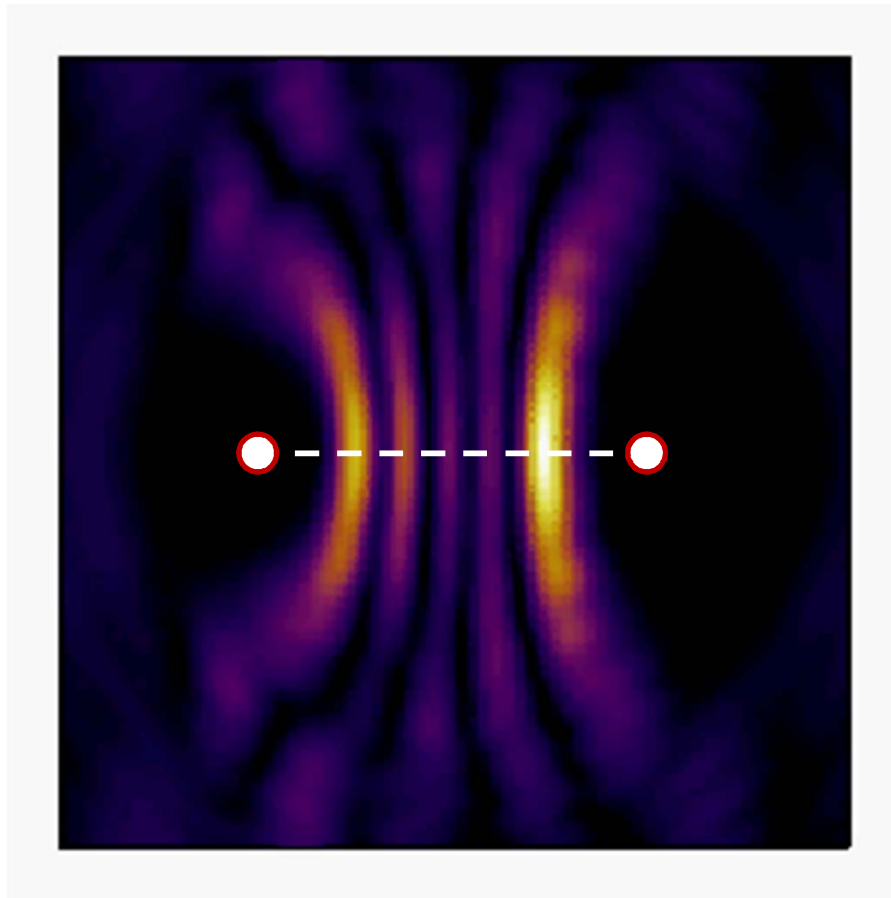
- reservoir dynamics

$$\partial_t N(x, t) = -\underbrace{[\Gamma_R + \beta R_R |\psi(x, t)|^2]}_{\text{decay}} N(x, t) + \underbrace{P(x)}_{\text{laser pump}} + \overbrace{D\nabla^2 N}_{\text{diffusion}}$$



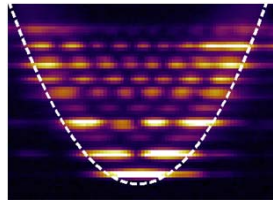
Nature Physics 8, 190 (2012)

Simulation results

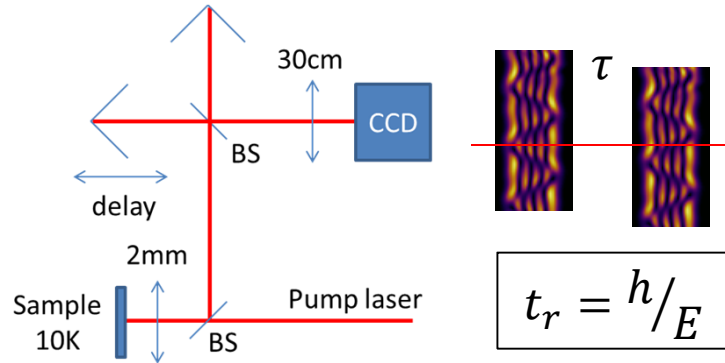


Resembles oscillating dark-solitons

How to measure?



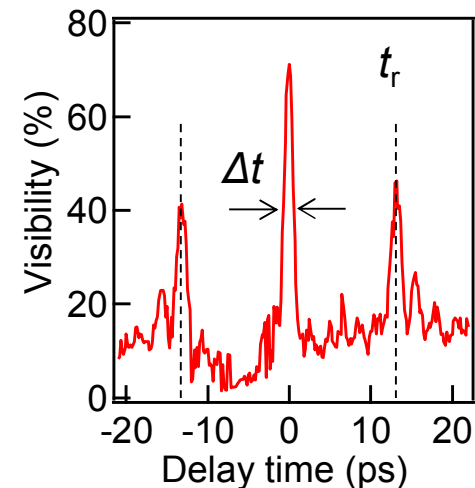
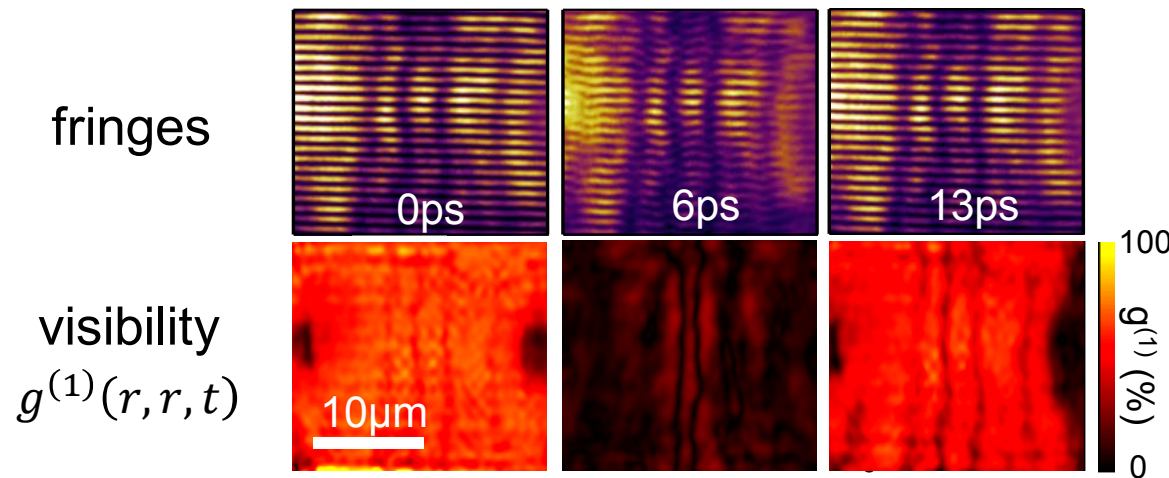
Condensate dynamics



- modelocking condensates

nonlinear optics

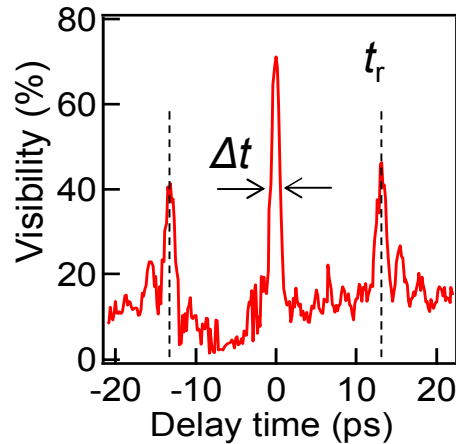
cf. ultrafast lasers, supercontinuum generation



- self-interference every round trip time (exact match)
- all the simple harmonic oscillator levels are phase coherent
- implies **spontaneous** soliton oscillations, not static

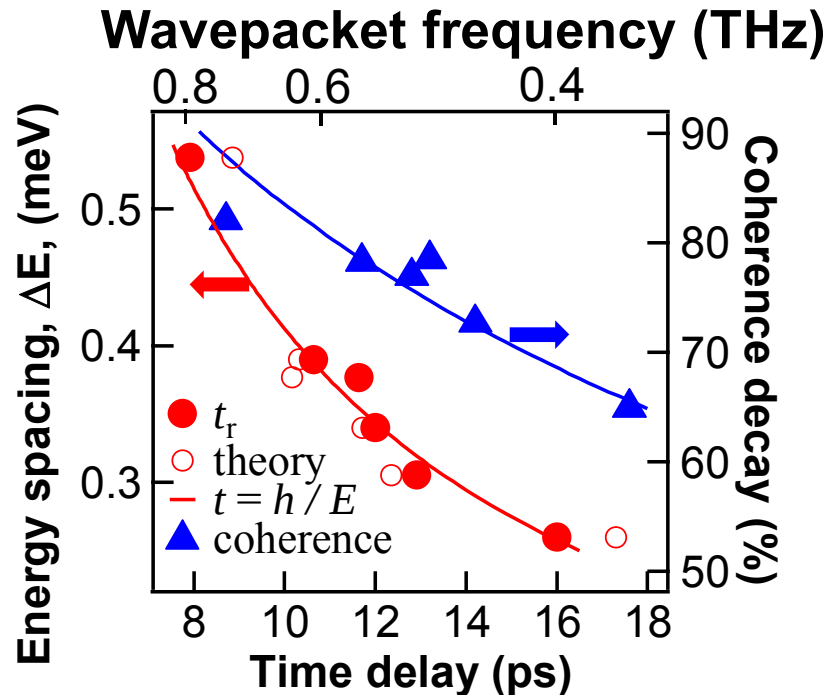
Nature Physics **8**, 190–194 (2012)

Tuneable oscillator



temporal width $\Delta t \simeq t_r/n_{SHO}$
 set by number of SHO states ($n_{SHO}=10$)

$$t_r = \pi L \sqrt{\frac{m^*}{2(g|\psi|^2 + \hbar R_R N)}}$$



wavepacket revival is not perfect
 decays over 40ps

- due to coherent wavepacket
- dispersion (SHO spacings)
 - decay
 - dephasing
 - diffusion

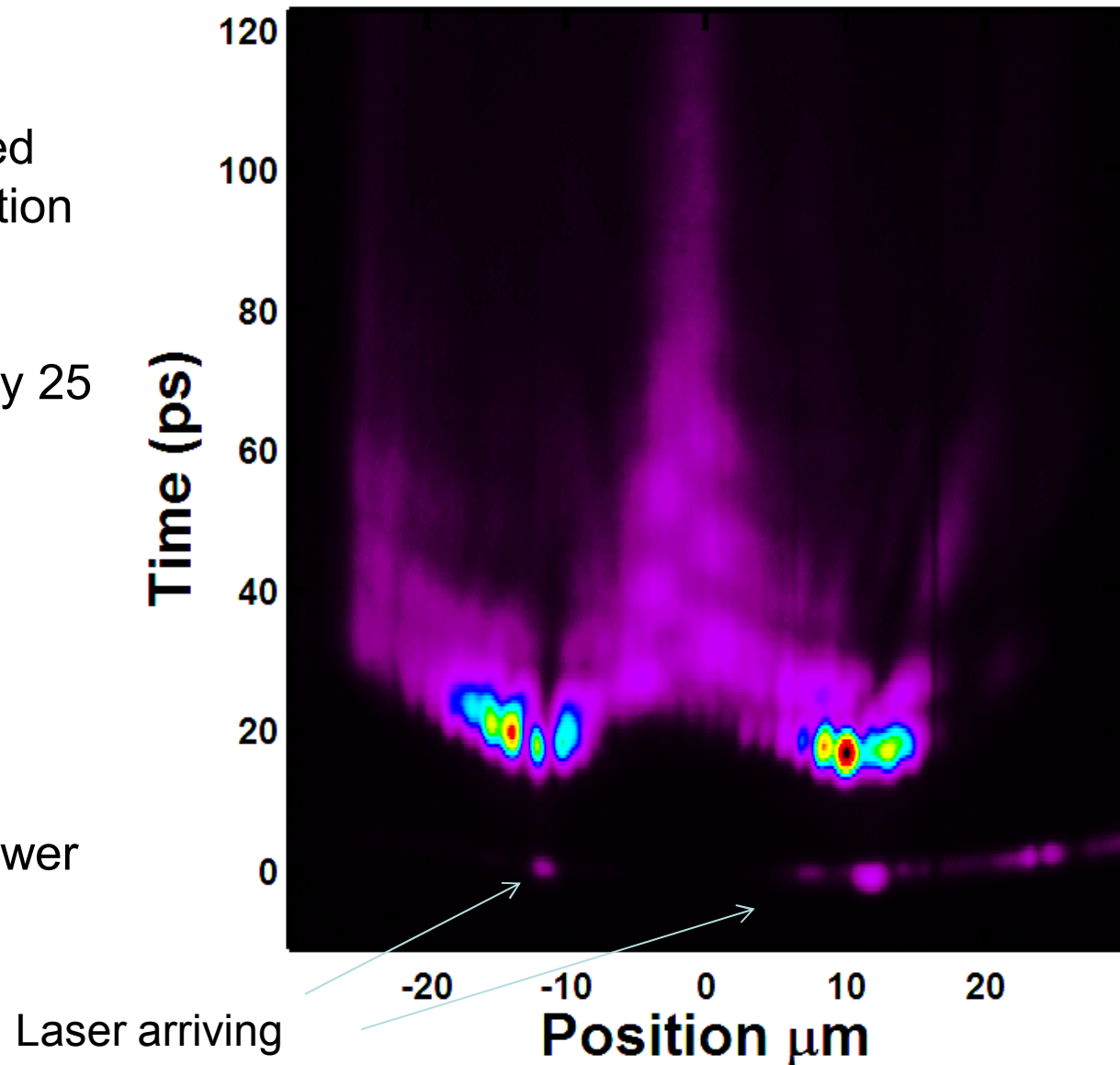
Polariton Quantum Pendulum

Oscillations observed
under pulsed excitation
regime

2 spots separated by 25
microns

Streak camera
measurement

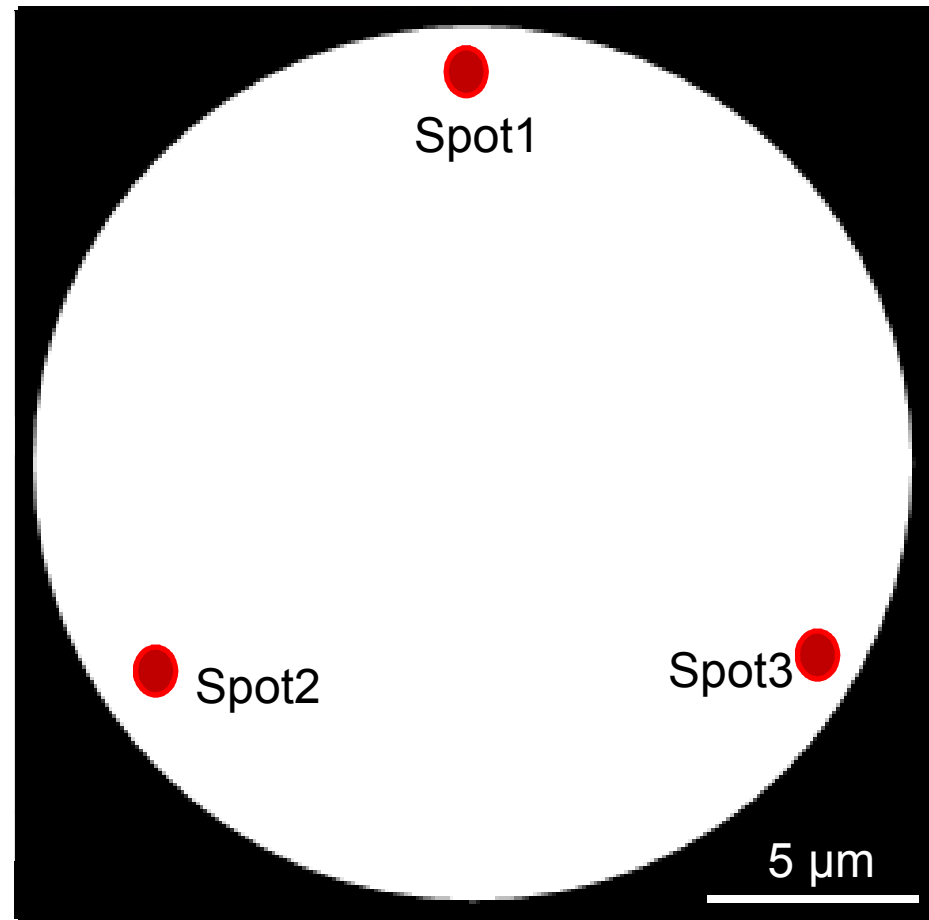
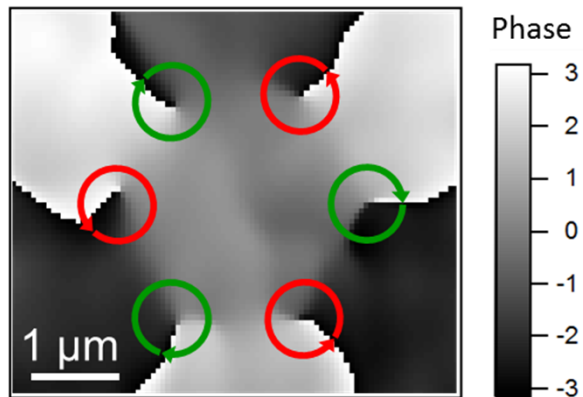
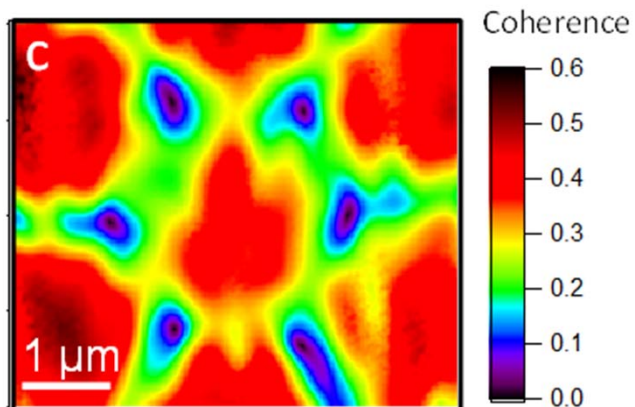
Increasing pump power



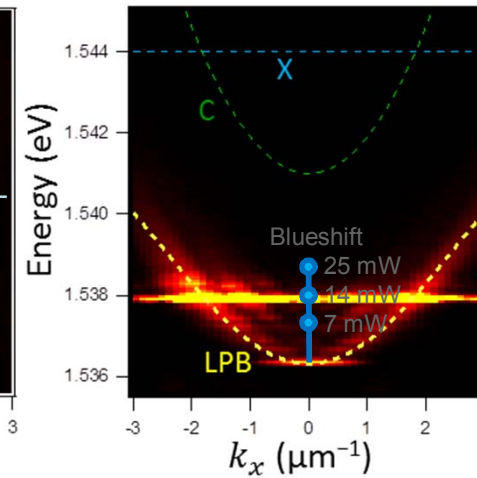
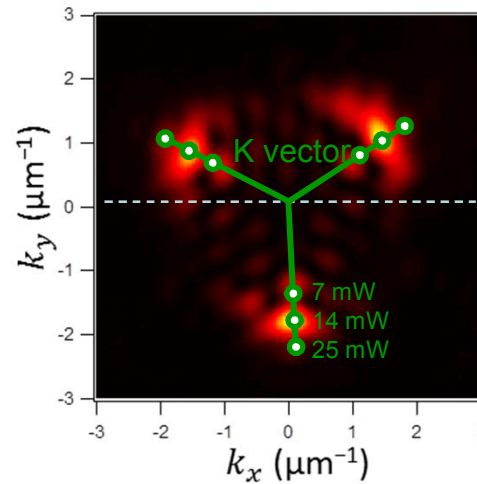
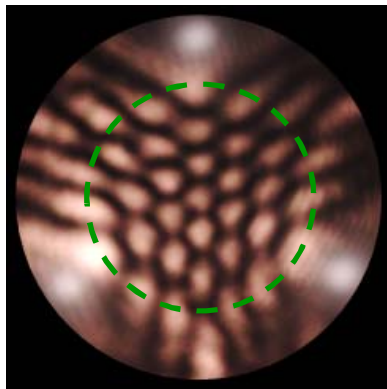
Multiple spot excitation

Vortex lattices

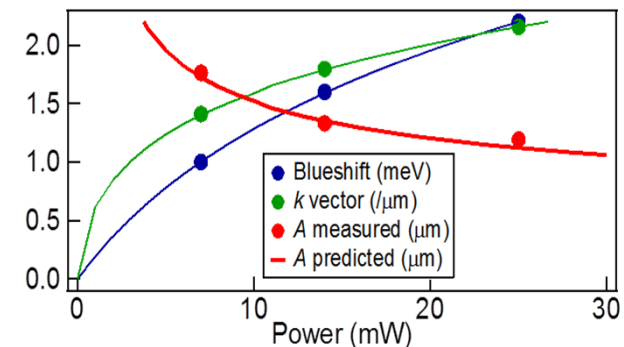
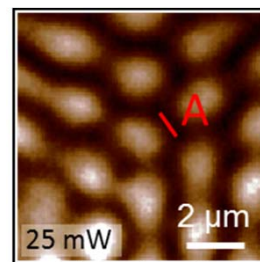
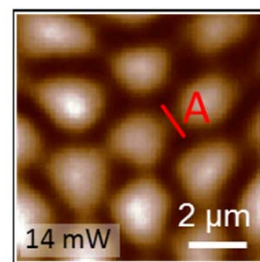
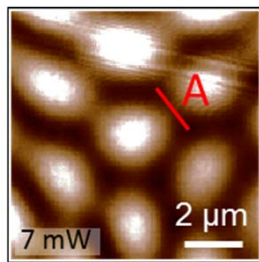
- honeycomb lattice of up to 100 vortices and anti-vortices



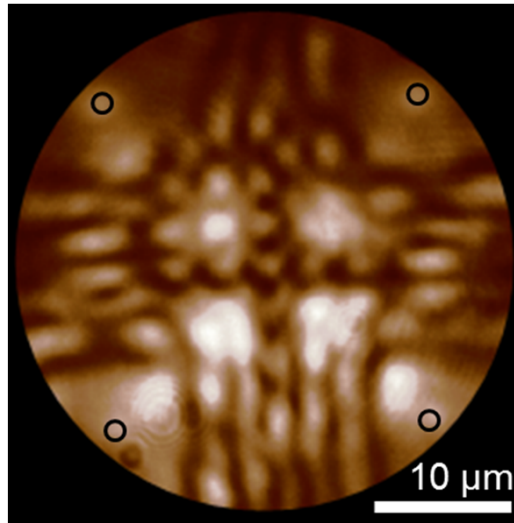
Stretching the lattice



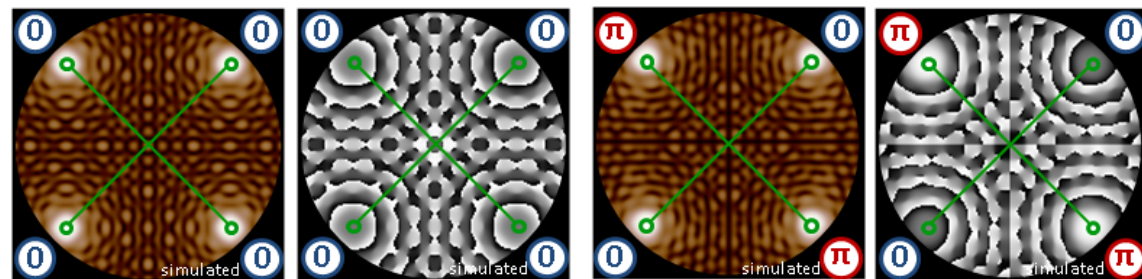
- Vortices formed by a linear superposition of 3 waves outflowing from each spot.
- Average distance between neighbouring vortices: $A = 4\pi/(3k\sqrt{3})$
- Outflow momentum dependent on power: $k(r) = K[\omega_c - \Delta(r)]$



Square lattice

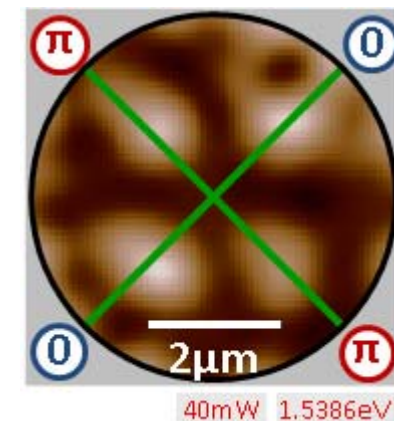
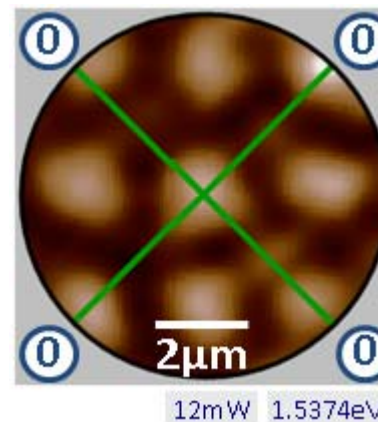
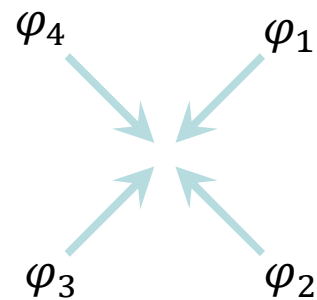


CGL simulations



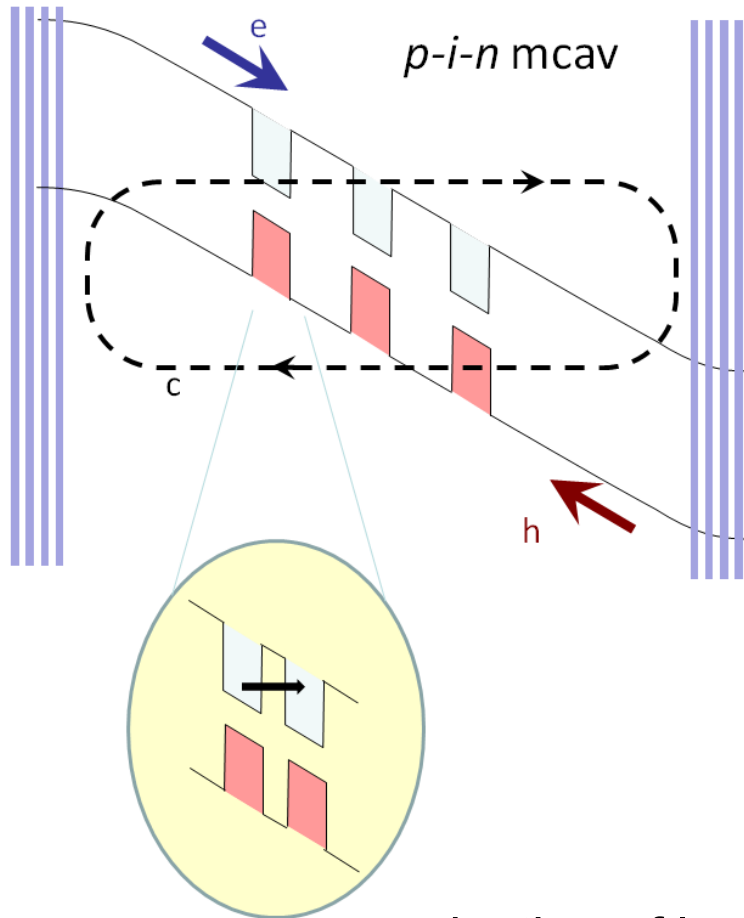
Ferromagnetic like

Antiferromagnetic like



Indirect polaritons: Dipolaritons

Indirect polaritons: Dipolaritons



Dipolariton approach:
weakly-coupled double quantum wells

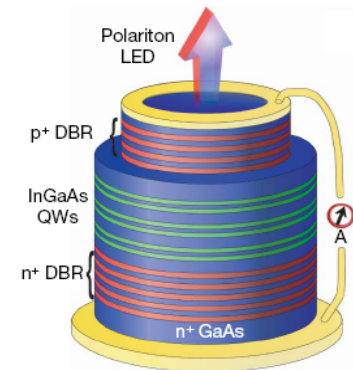


direct control of polariton dipole

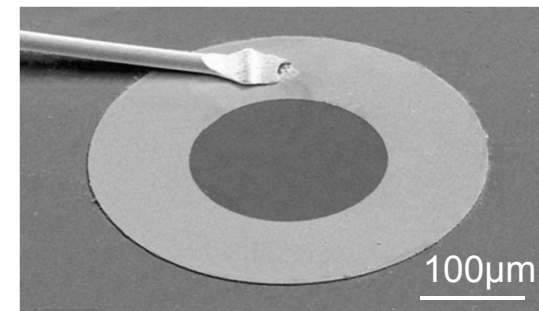
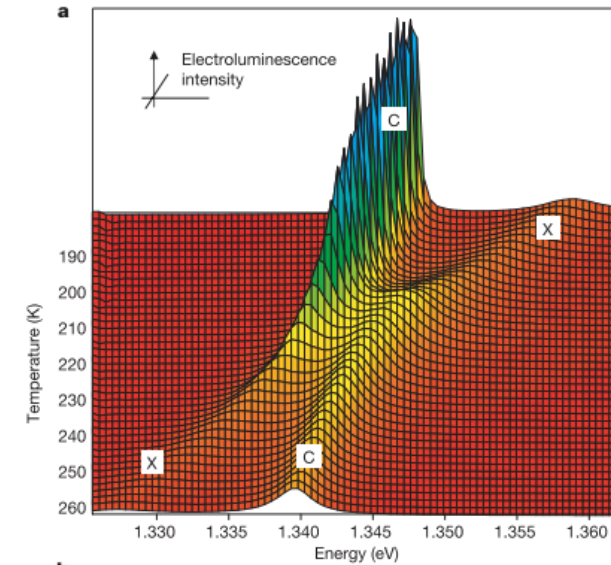
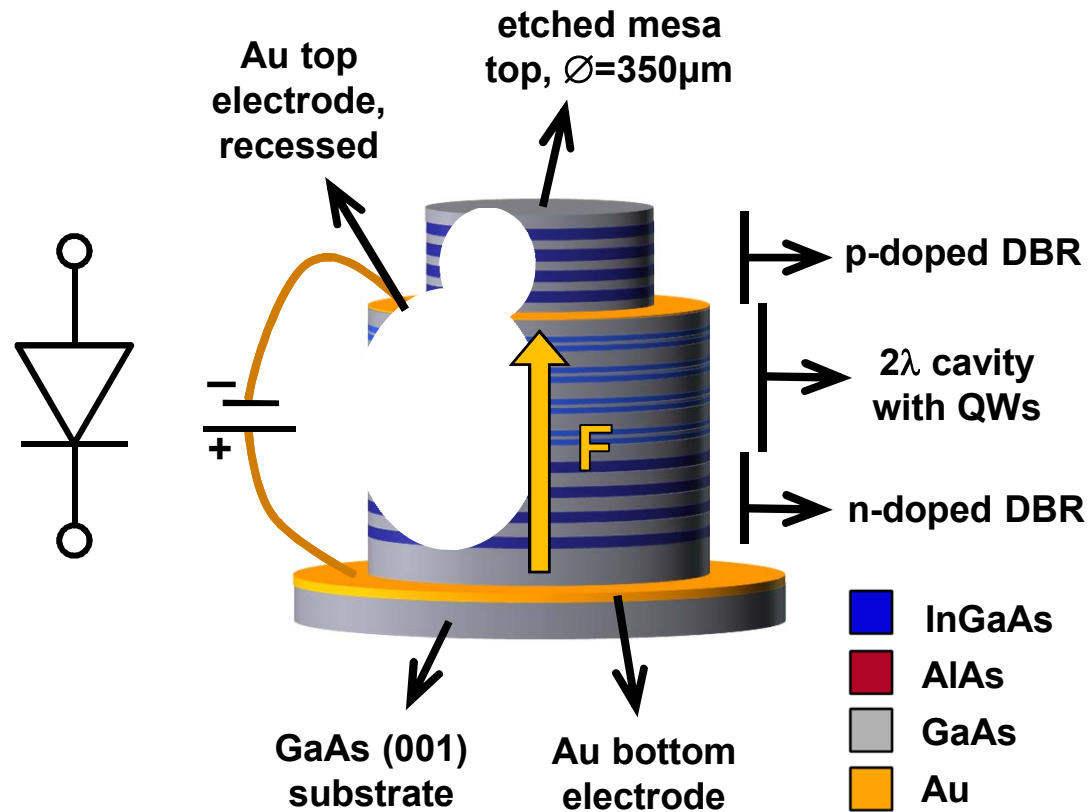
$$H_{PP}^{eff} = \frac{1}{2} \sum_{k,k',q} \frac{a_B^2}{A} V_{k,k',q}^{PP} \hat{p}_{k+q}^+ \hat{p}_{k'-q}^+ \hat{p}_k \hat{p}_{k'}$$

dipole-dipole

- reduction of lasing threshold
- electrically-pumped polariton lasers and BECs

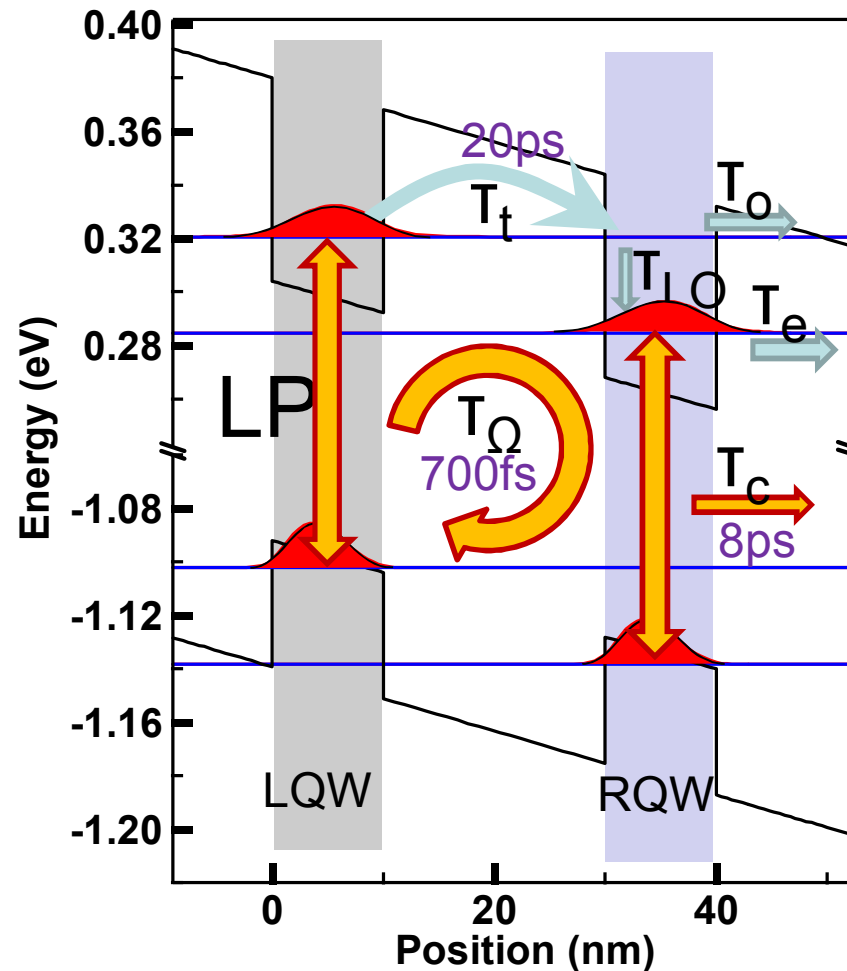
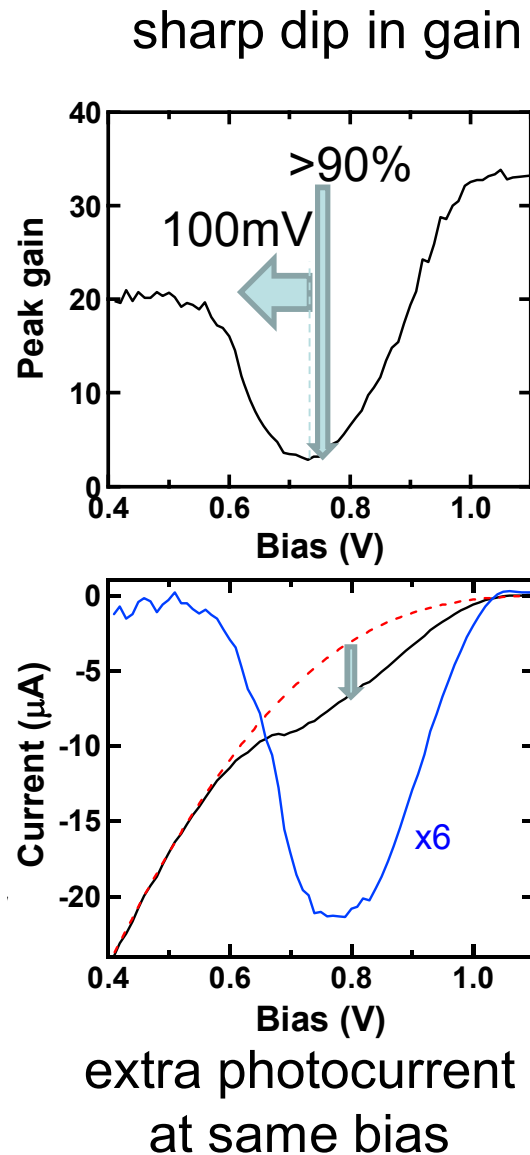


Biased samples: Polariton LED structure



"A GaAs light-emitting diode operating near room temperature", *Nature* **453**, 372-375 (2008)

Motivation

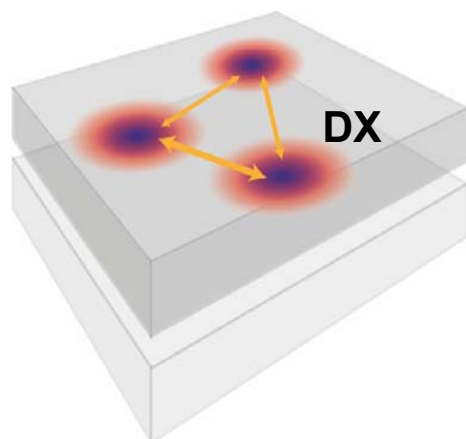
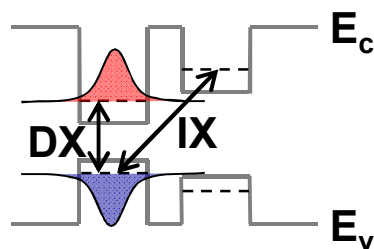


Control of polariton parametric scattering due to LO phonon assisted tunnelling with a double QW microcavity

“Control of polariton scattering in resonant-tunneling double-quantum-well semiconductor microcavities”, *Phys. Rev. B* **82**, 113308 (2010)

Dipolaritons

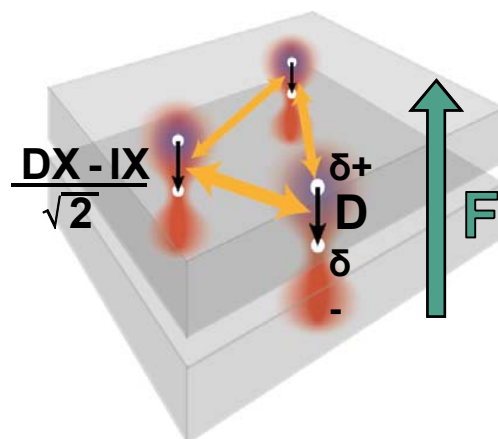
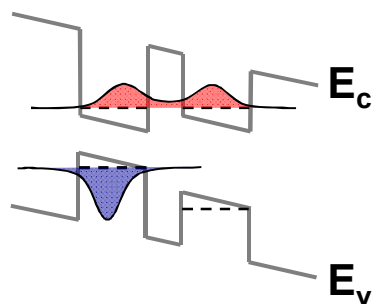
electron levels
off resonance



“tunnelling off”

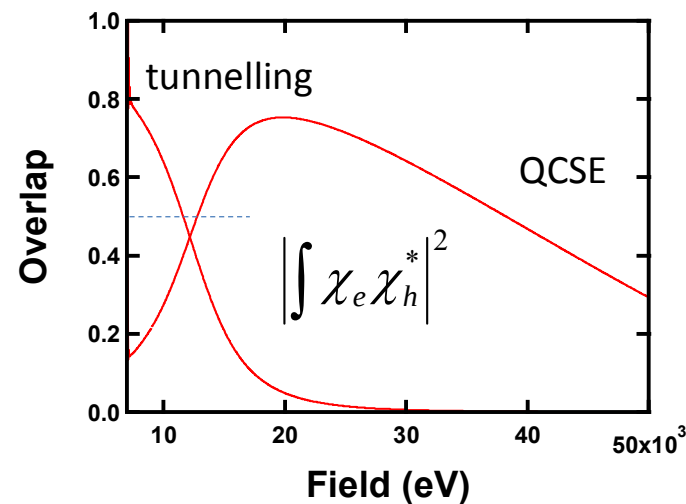
direct excitons
DX

electron levels
at resonance

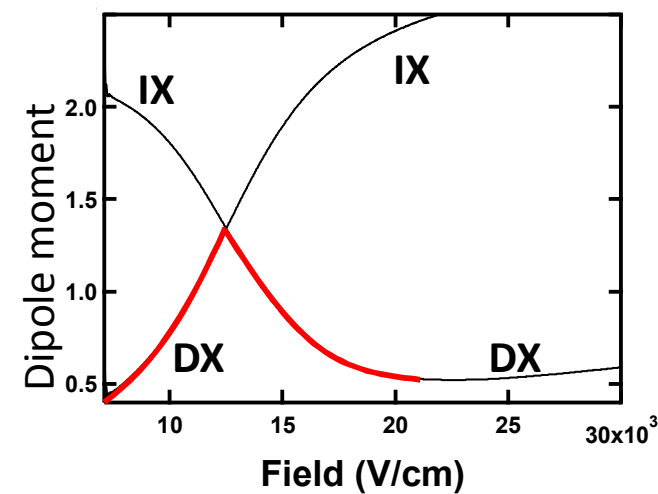


“tunnelling on”

mixed excitons
DX±IX,
static dipole
moment



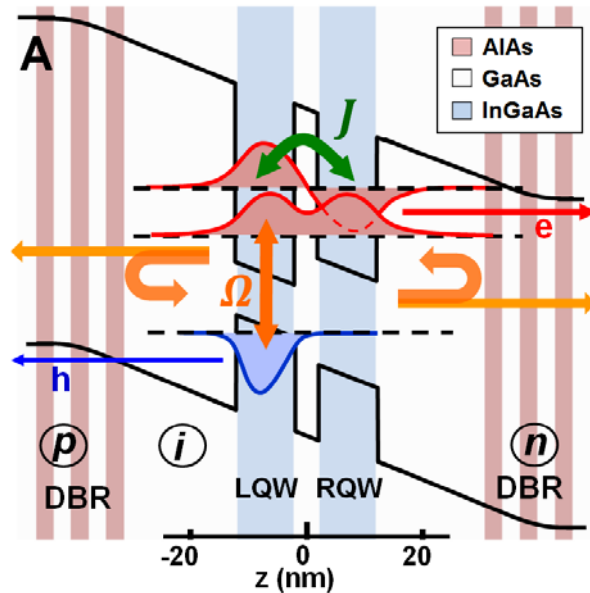
Oscillator strength is kept



Strong dipole moment

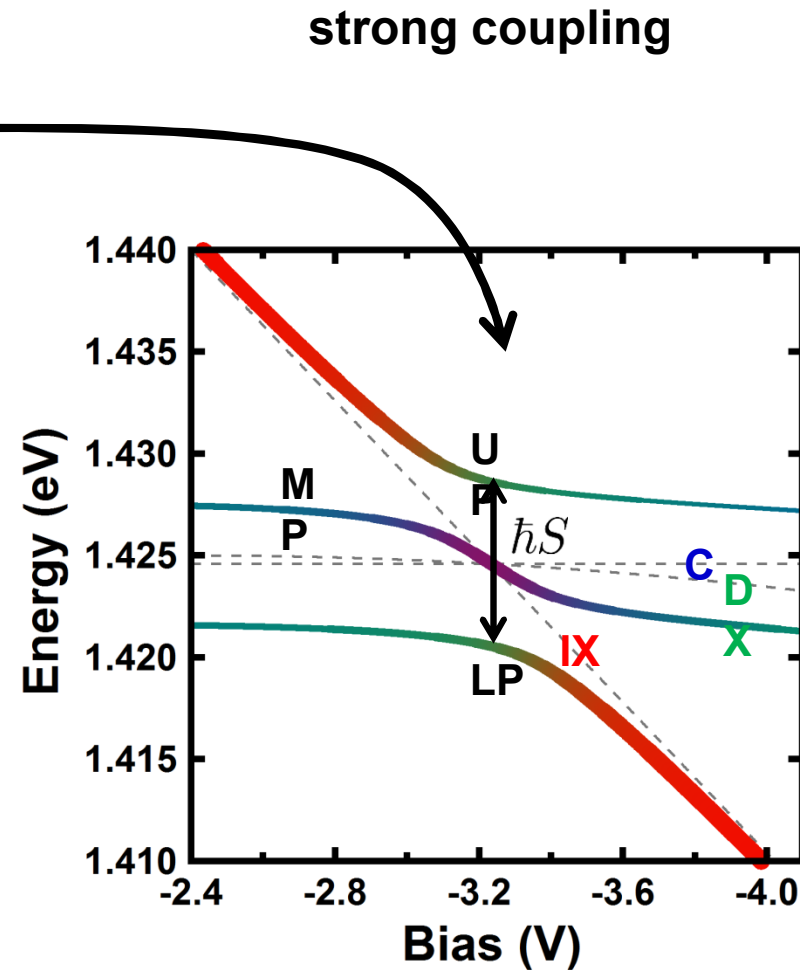
“Oriented polaritons in strongly-coupled asymmetric double quantum well microcavities”, *Appl. Phys. Lett.* **98**, 081111 (2011)

Dipolaritons

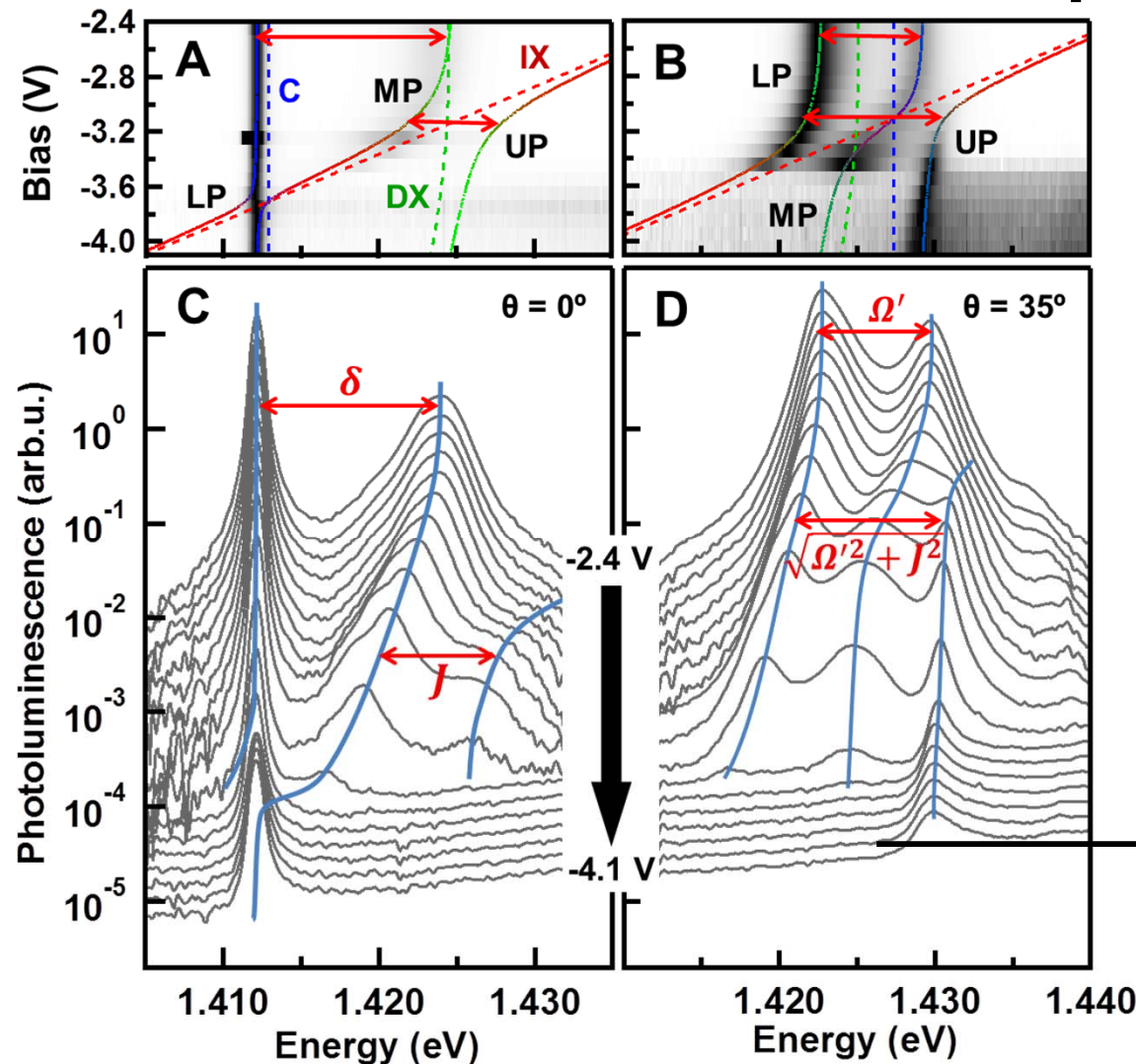


Combining tunnel coupling (J) and Rabi splitting (Ω)

$$H = \begin{pmatrix} E_C & \Omega/2 & 0 \\ \Omega/2 & E_{DX} & J/2 \\ 0 & J/2 & E_{IX} \end{pmatrix}$$



Observation of dipolaritons



Photoluminescence of the system versus increasing bias for detuned and resonant cavity

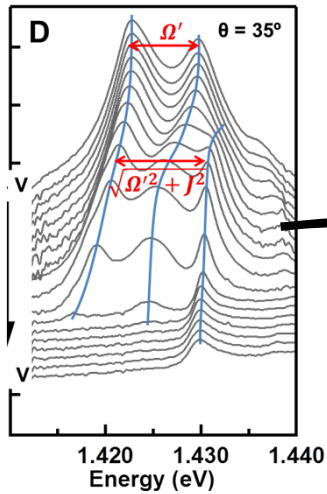
PL is lost because electron tunnel out of the system

tunnel-split
excitons,
uncoupled cavity

dipolaritons,
strong coupling of
 J and Ω

“Coupling Quantum Tunneling with
Cavity Photons”
Science **336**, 704 (2012)

Dipolaritons at resonance



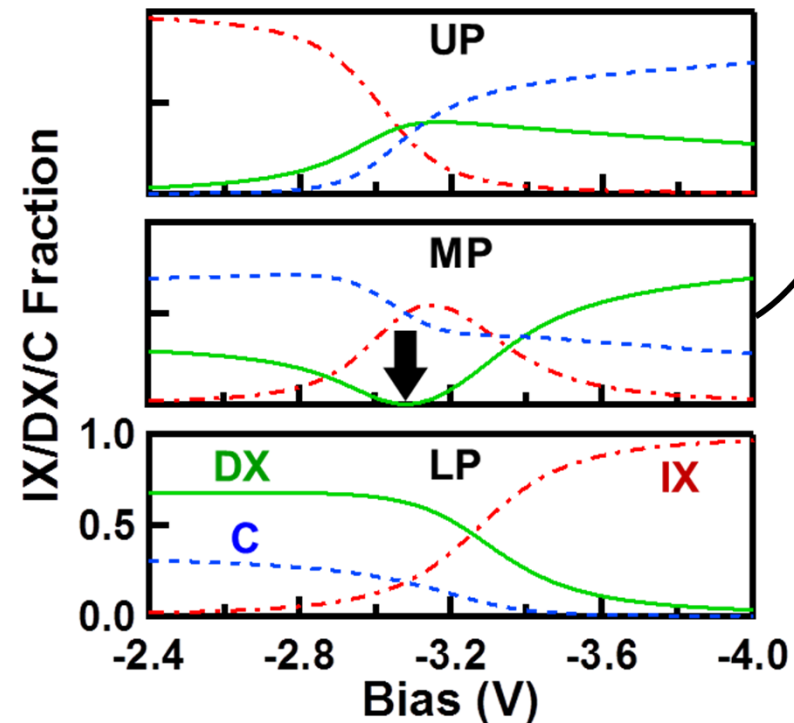
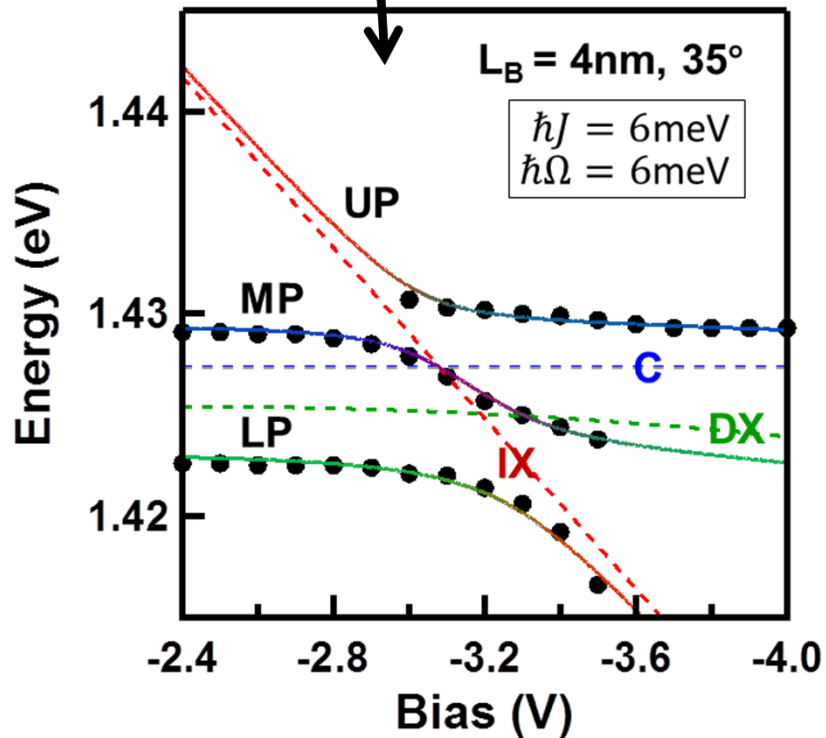
peak extraction

+

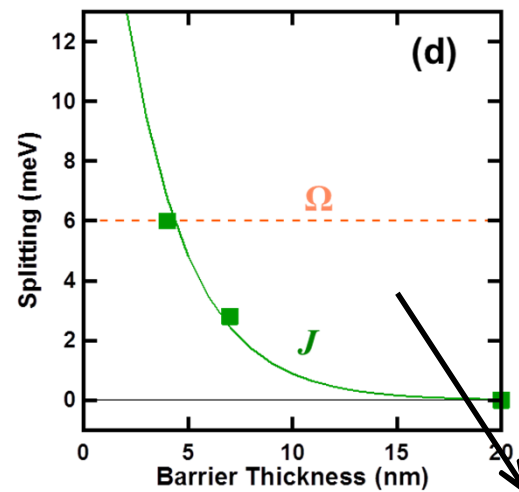
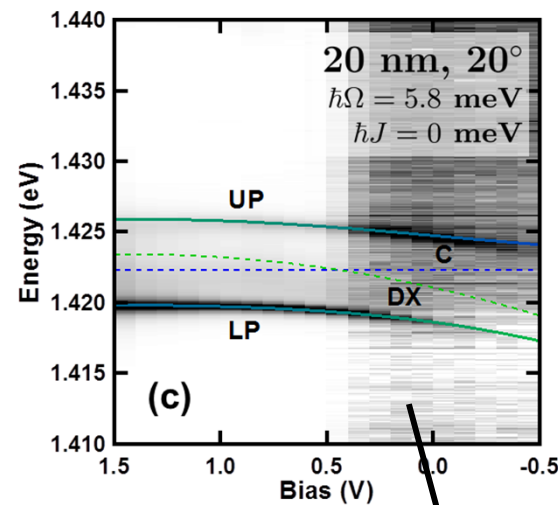
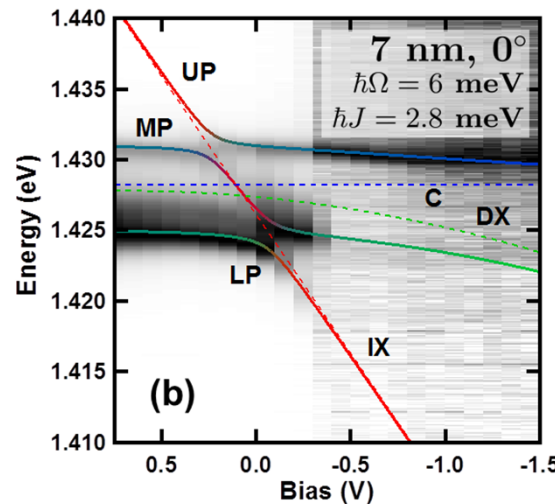
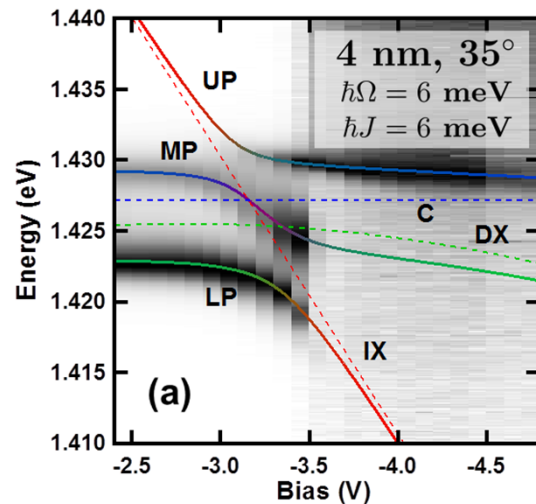
$$H = \begin{pmatrix} E_C & \Omega/2 & 0 \\ \Omega/2 & E_{DX} & J/2 \\ 0 & J/2 & E_{IX} \end{pmatrix}$$

MP – state: no DX!

$$|MP\rangle = \frac{\Omega|IX\rangle - J|C\rangle}{S}$$



Barrier width dependence



Influence of the
**tunnelling barrier
thickness** (4,7,20nm) on
the bare tunnelling rate J

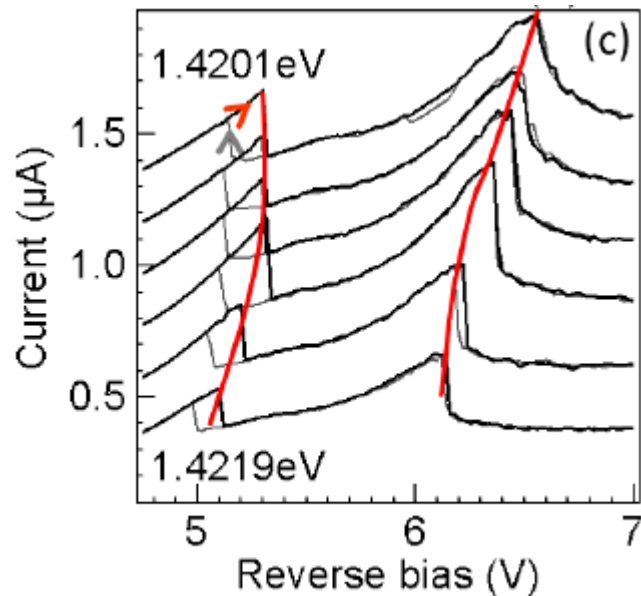
Excellent agreement with
solution of the
Schrödinger equation for
tunnel coupling

no tunnel coupling normal
polariton regime

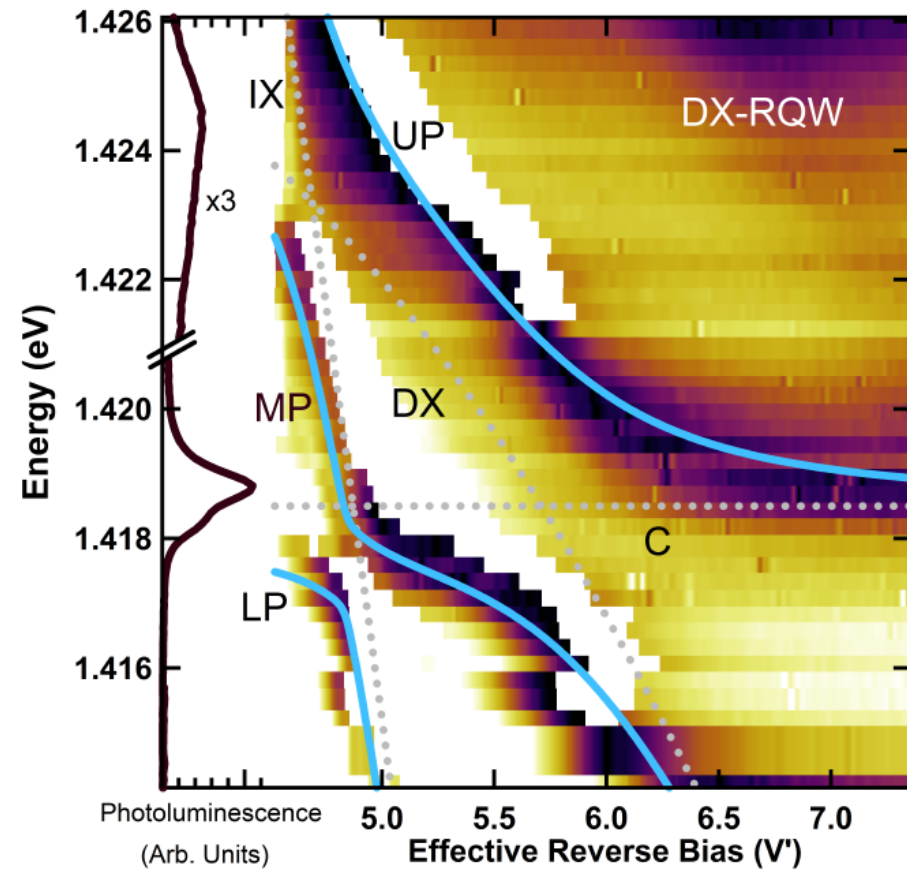
ADQW simulation from
solving Schrödinger
equation

Observation through photocurrent

Experiment: Tuning laser energy while monitoring photocurrent



Strong coupling observed on photocurrent measurements
Hysteresis observed at resonance positions due to charge build-up



Mapping of the full dispersion curves
Excellent sensitivity on otherwise poorly optically active modes

Summary

- lasing threshold at 25K vs 70K (strong vs weak)

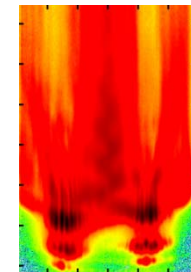
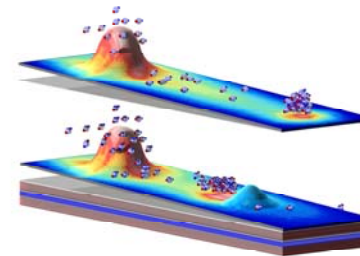
- Electrical control of polariton dispersions
tuning of the condensate energy



- Electrical and optical manipulation of polariton condensates on a chip

polariton condensate transistor

polariton condensate pendulum



Interactions between condensates in confining potentials

- Dipolaritons: Oriented polaritons
new possibilities for enhancing nonlinear Interactions
threshold reduction, control of parametric scattering

Thank you



FORTH

Microelectronics Research Group

Univ. of Crete

